

Fabrication and applications of ion traps

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Overview

1. Ion qubit

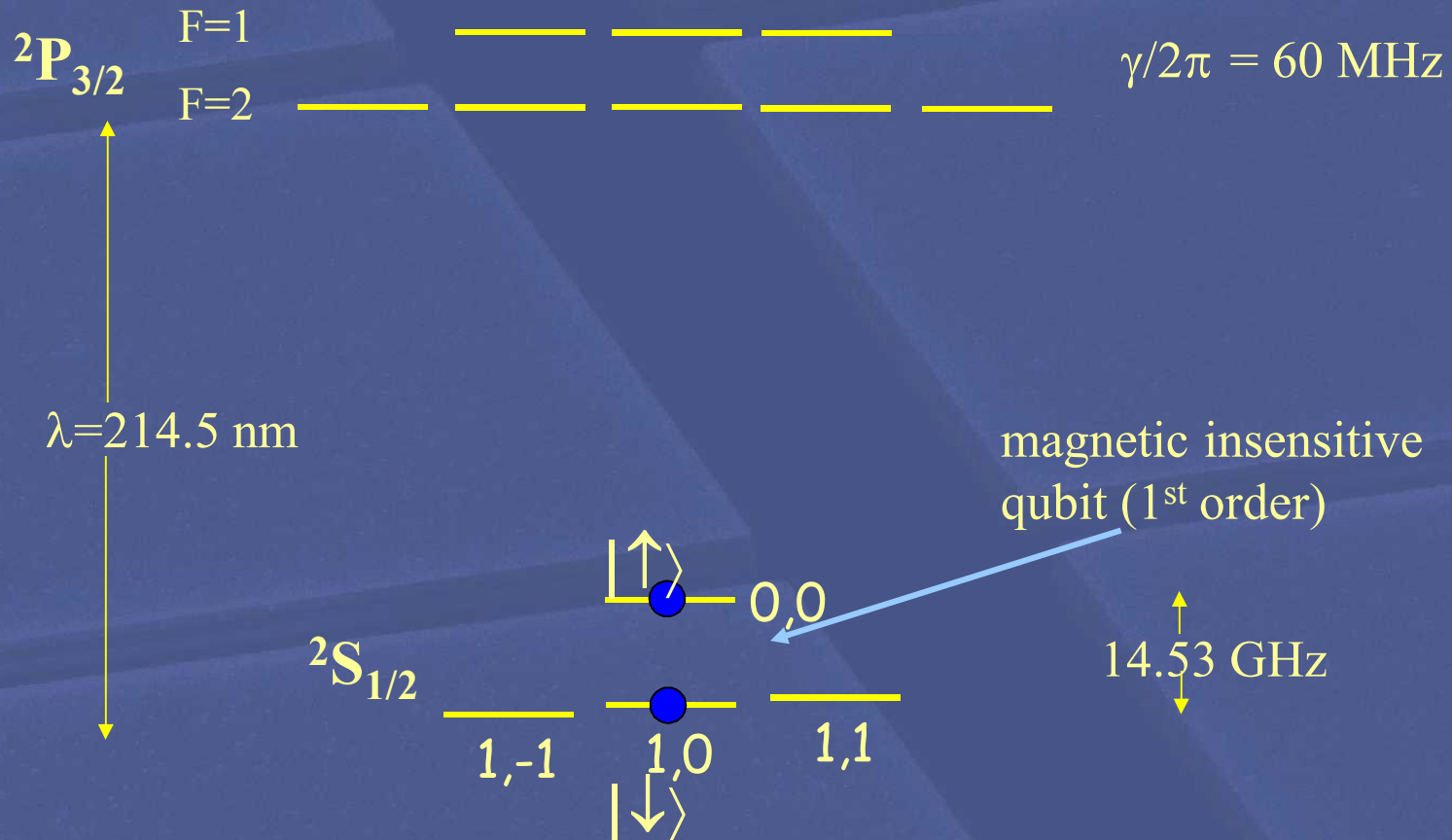
- a. Cadmium: hyperfine qubit
- b. Ytterbium: ion-photon entanglement
- c. Cadmium MOT: combining neutrals and ions

2. Trap development

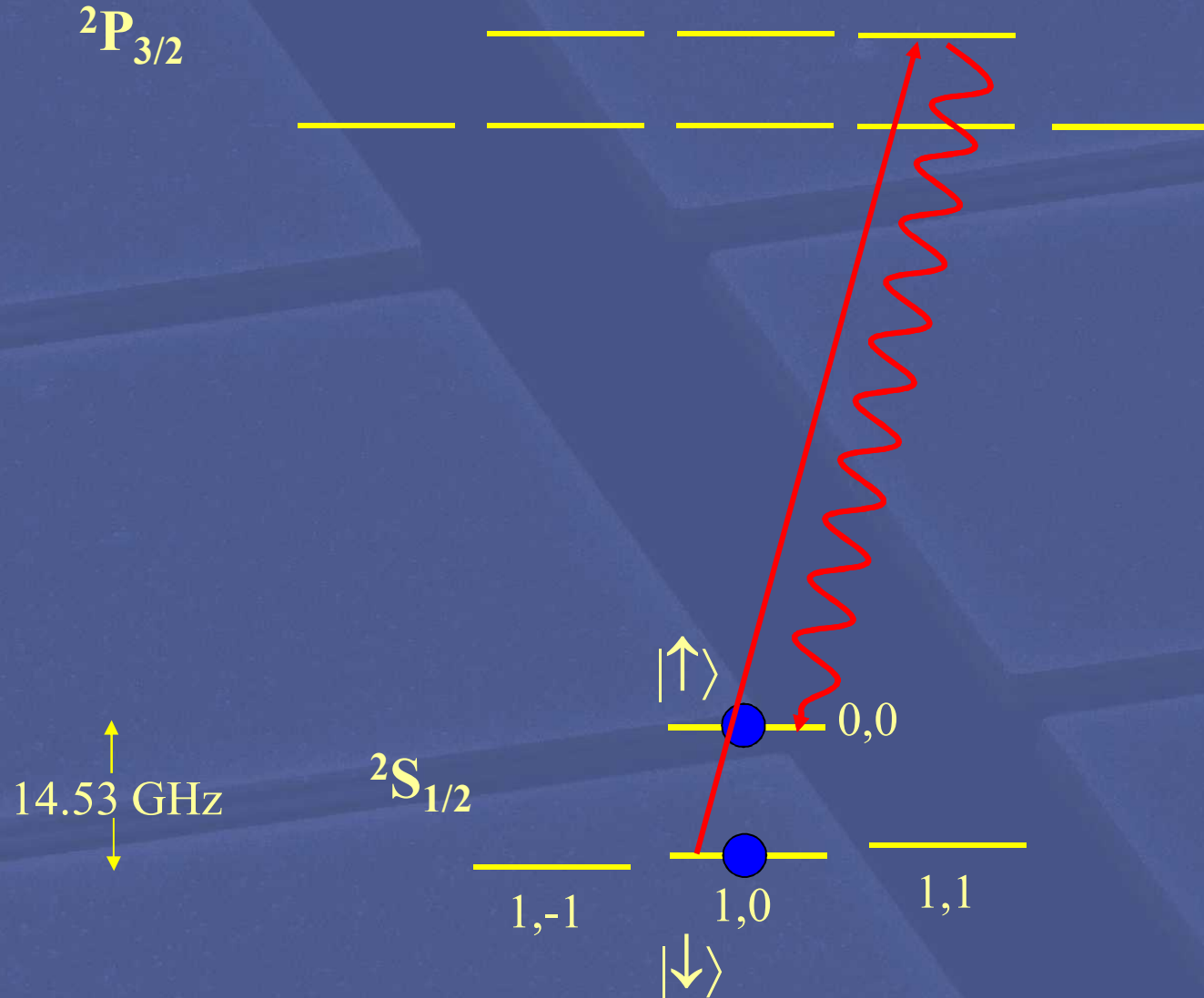
- a. General requirements/hurdles of microfabricated traps
- b. Anomalous heating
- c. Specific fabrication examples

1a. Cadmium qubit

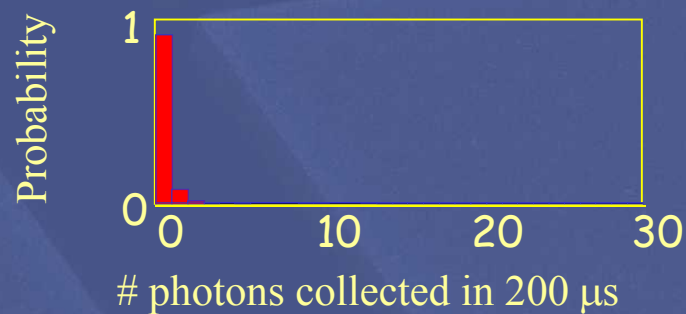
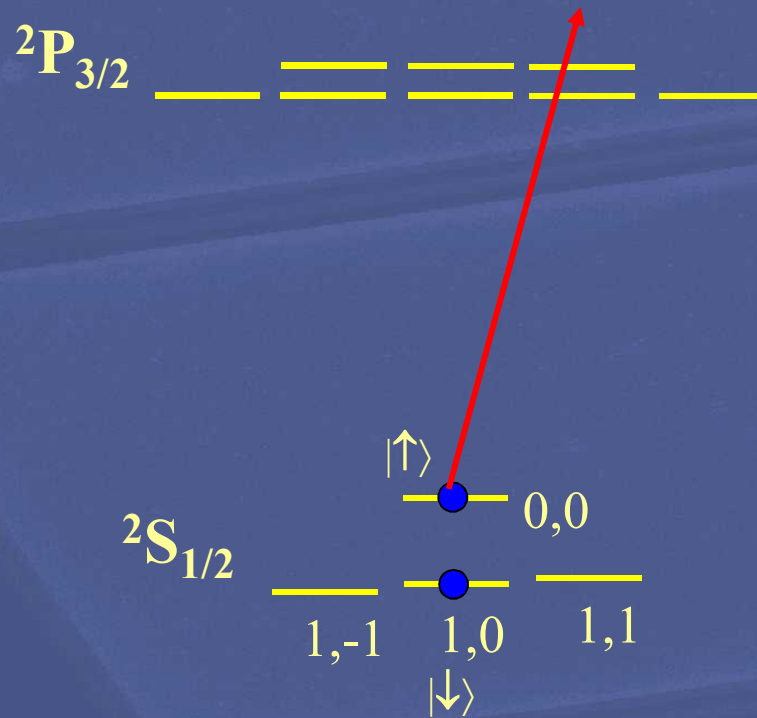
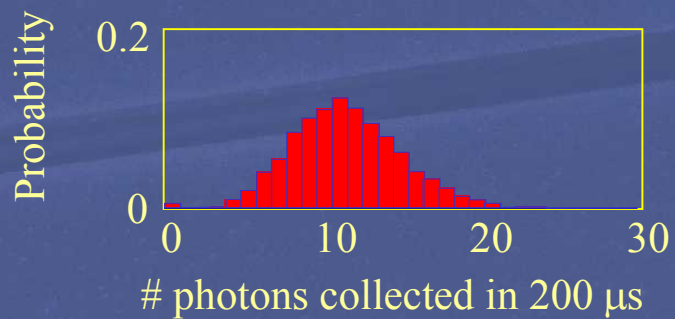
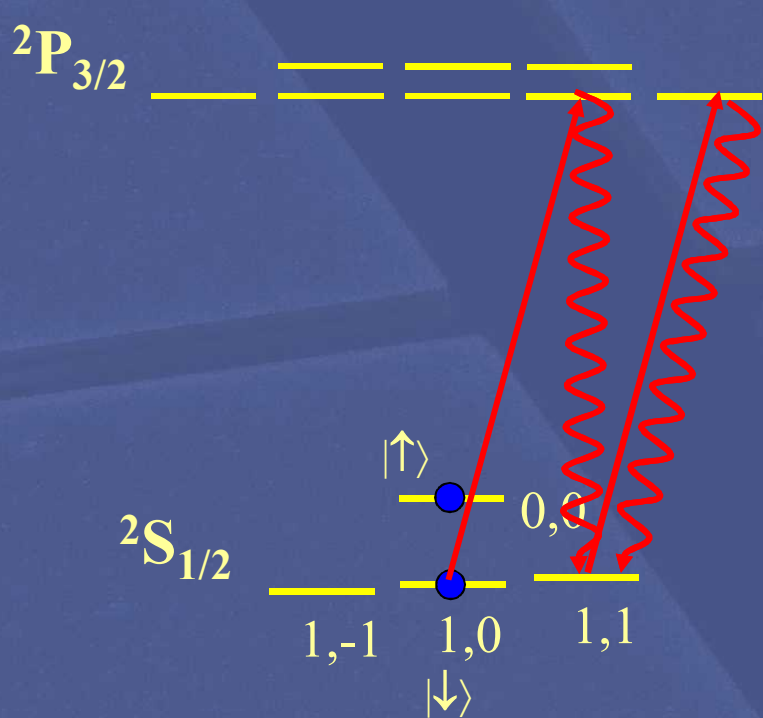
$^{111}\text{Cd}^+$ Energy Level Diagram



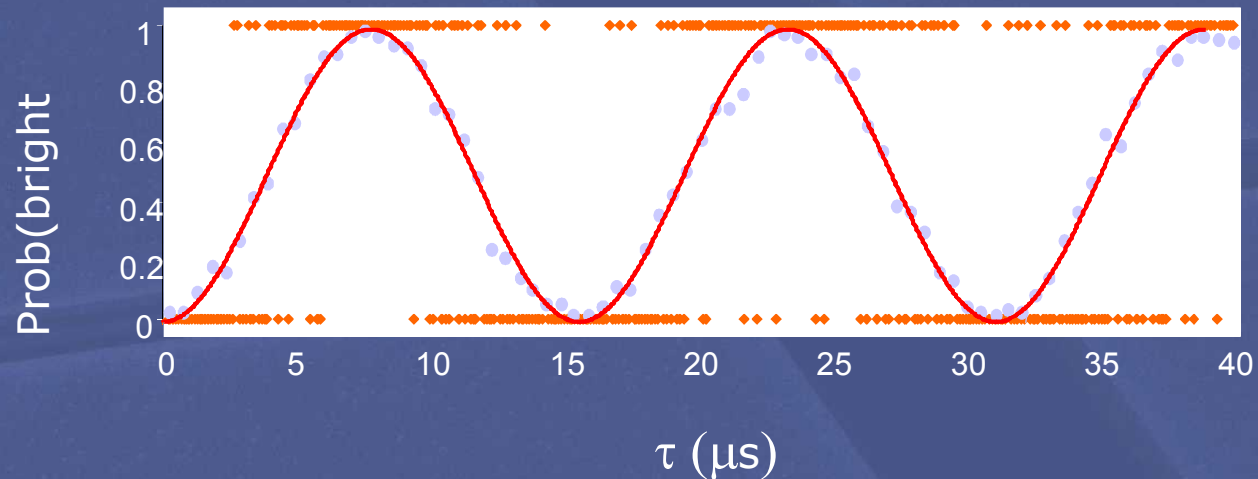
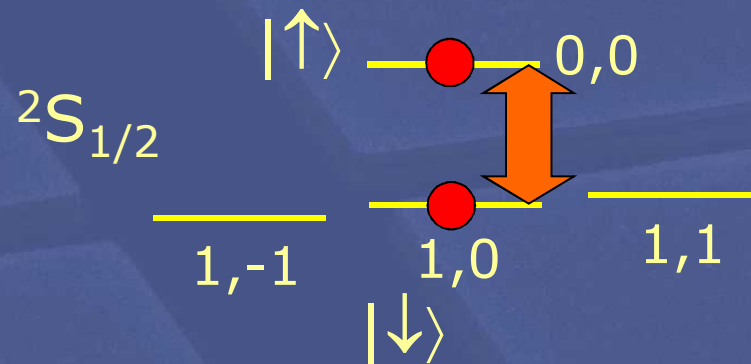
Initialization



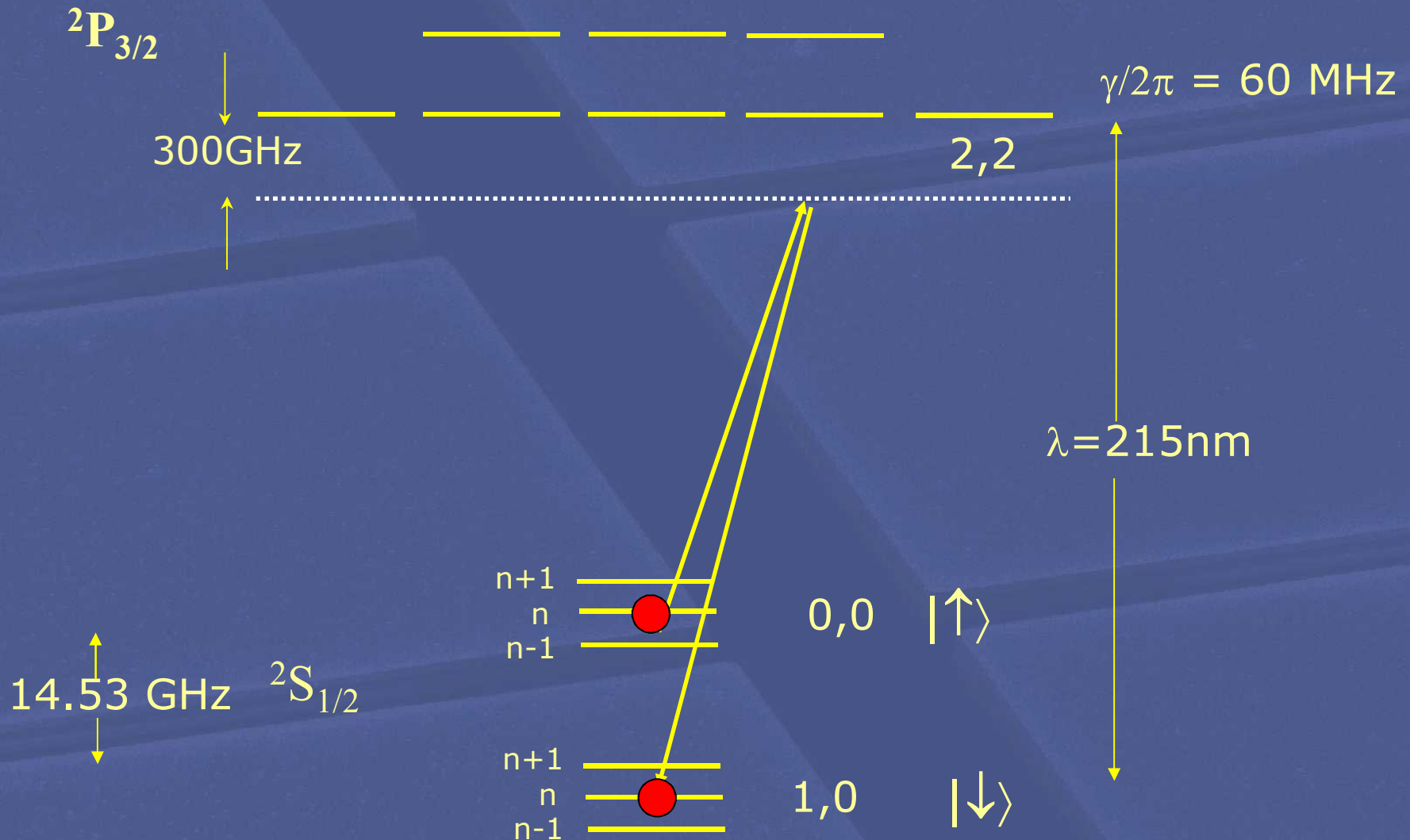
Detection



Qubit rotations: microwaves

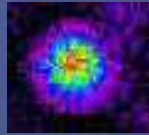


Raman transitions: motional sidebands



Cadmium vs. Ytterbium

Cadmium



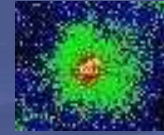
Pros:

- simple atomic structure

Cons:

- difficult wavelength
 - quadrupled diode-laser (complex, expensive)
 - low power
 - always free space

Ytterbium



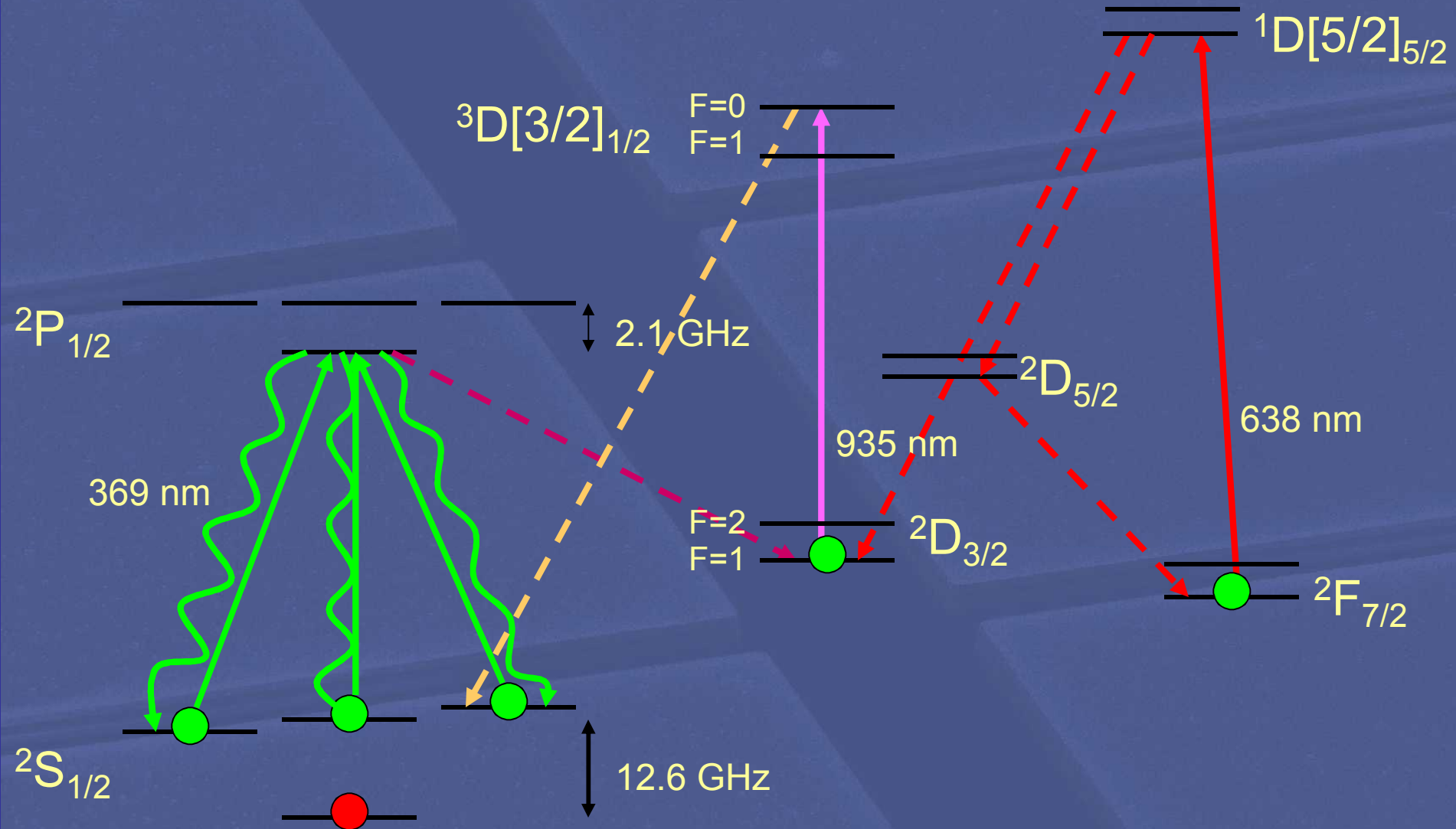
Cons:

- more complicated atomic structure
- more lasers

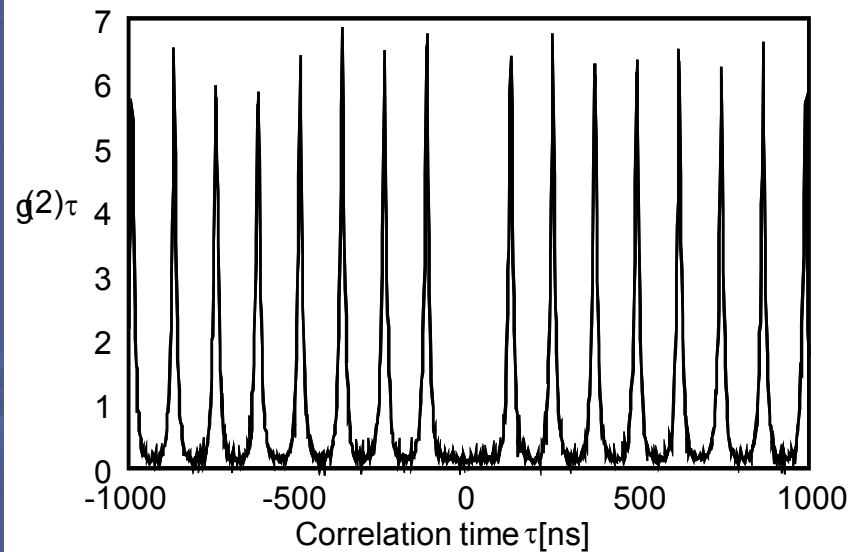
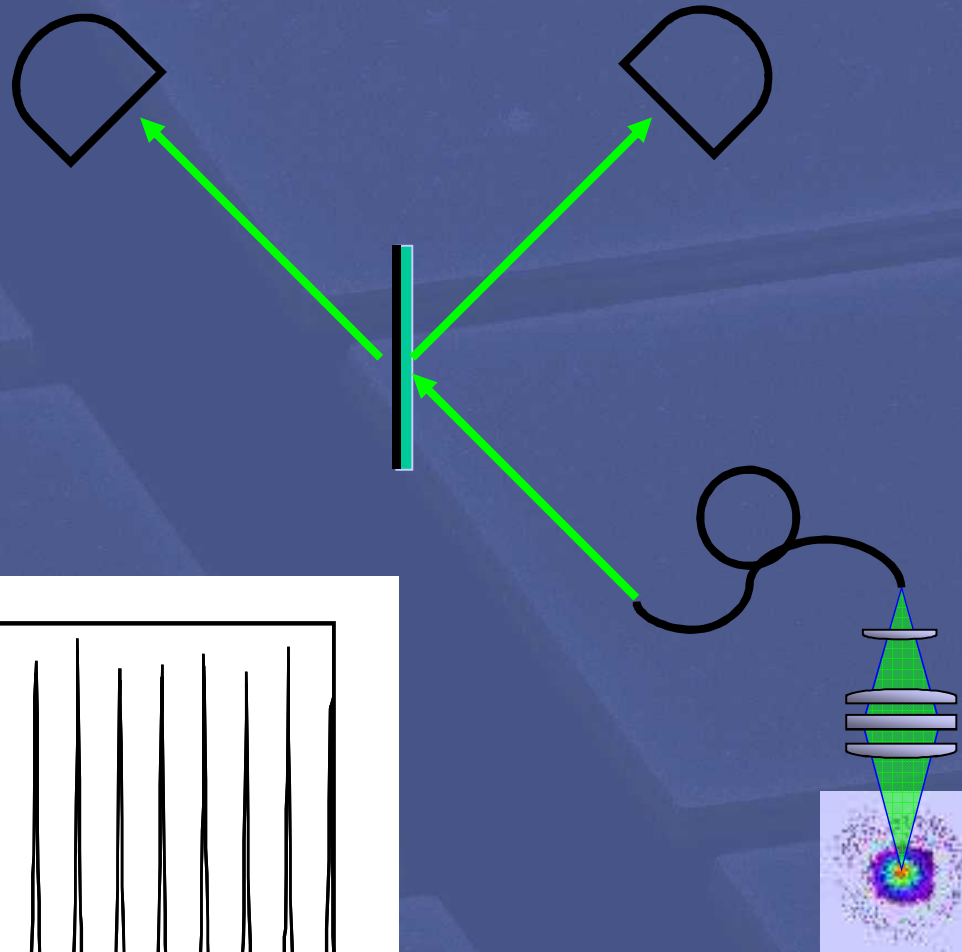
Pros:

- nice wavelengths
 - direct diode lasers (simple, cheap)
 - more power
 - *fibers*

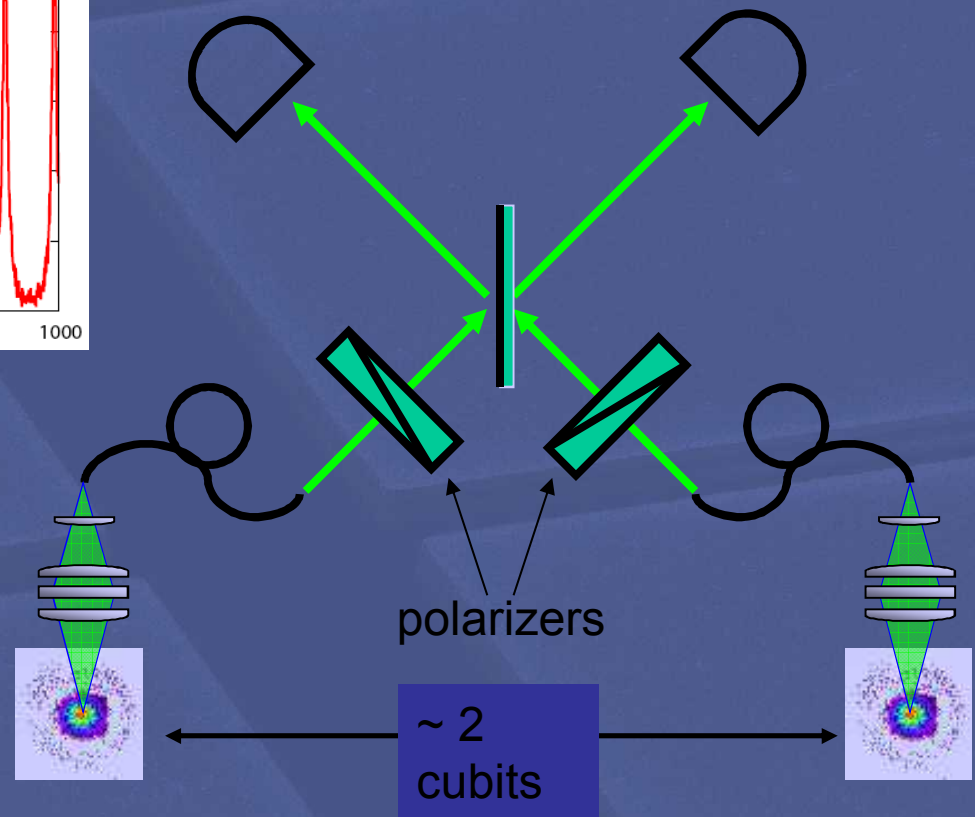
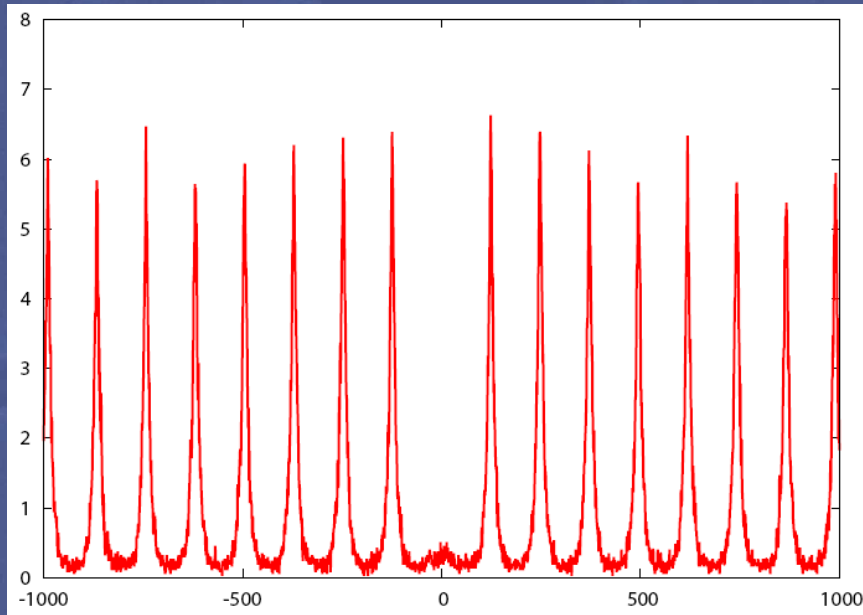
The Ytterbium ($^{171}\text{Yb}^+$) Ion



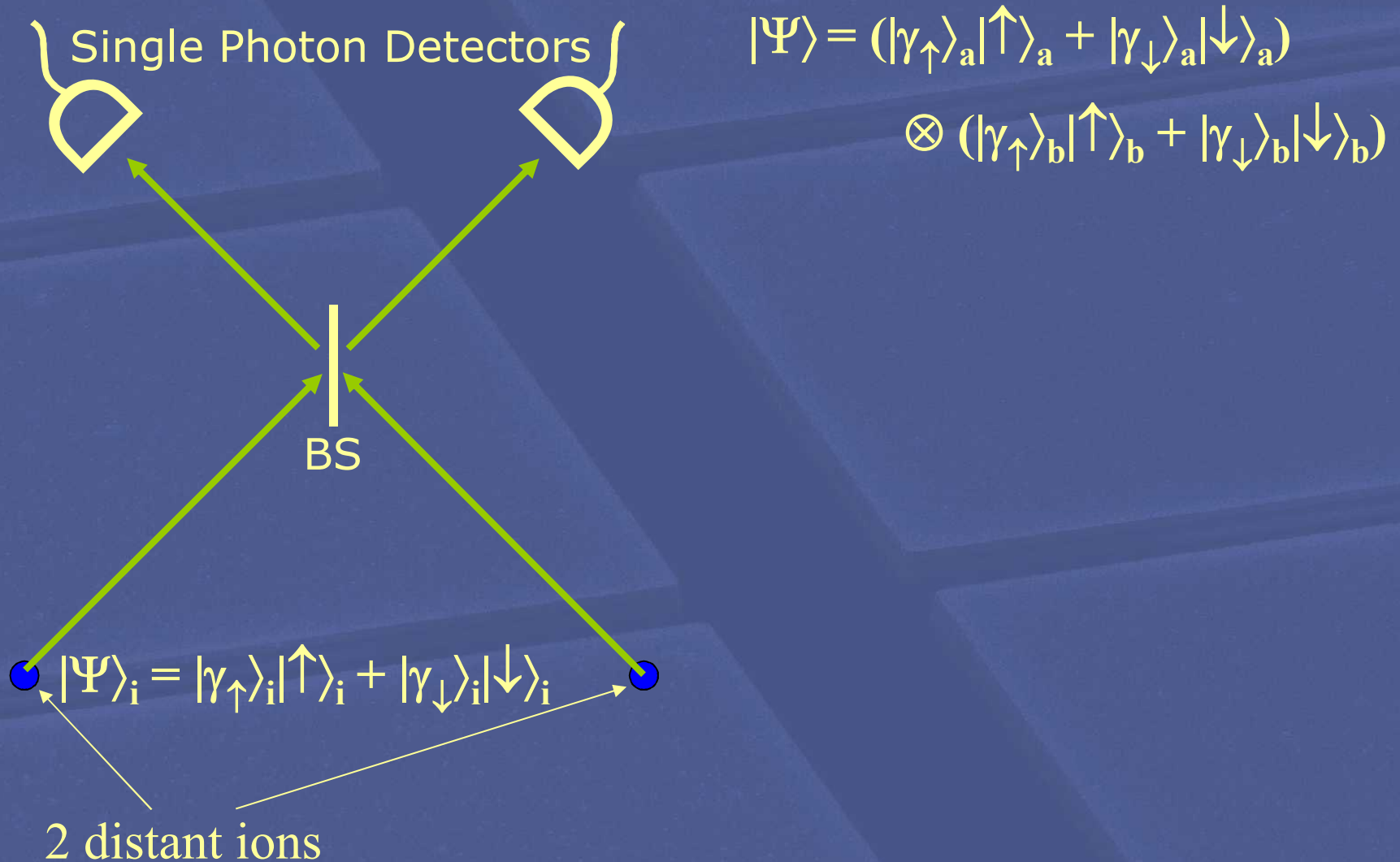
Single Photon Source



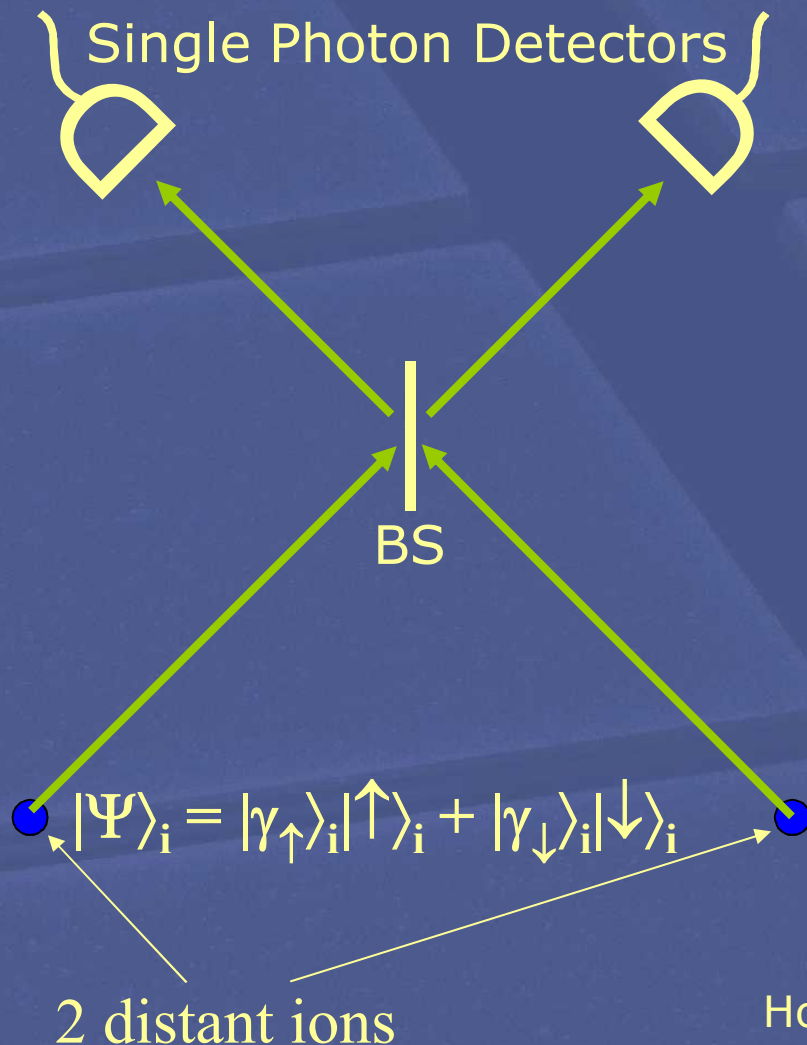
Two Photon Interference



Remote Ion Entanglement



Remote Ion Entanglement

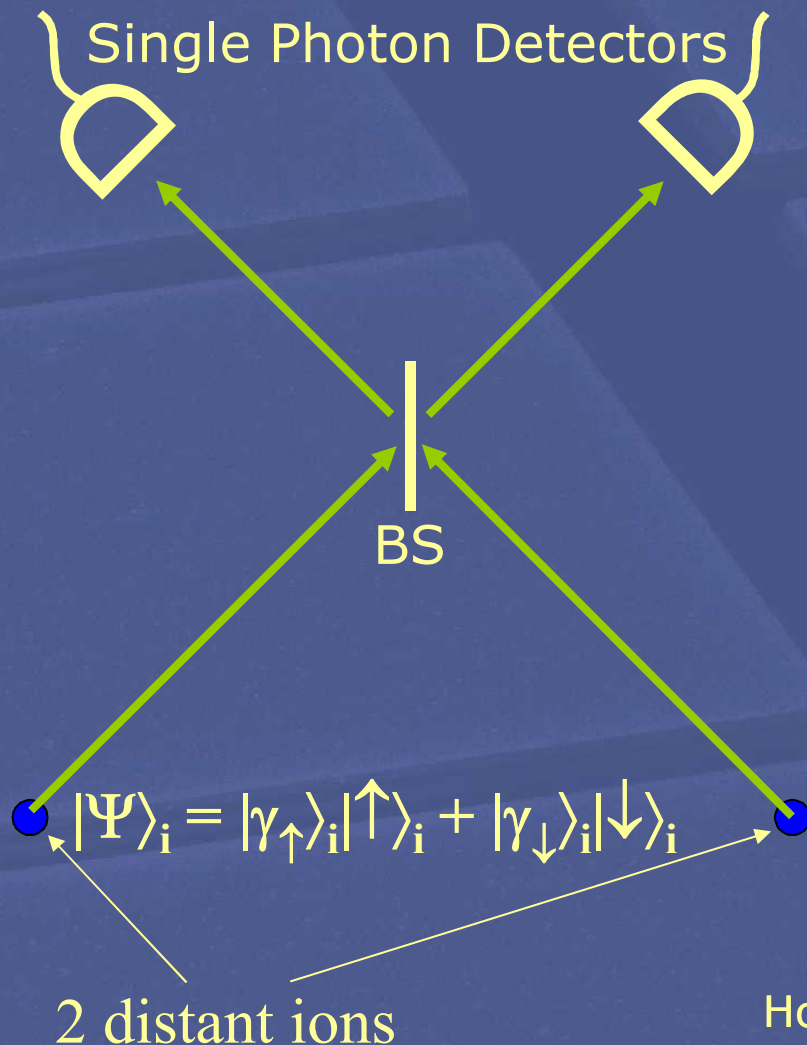


$$|\Psi\rangle = (|\gamma_{\uparrow}\rangle_a |\uparrow\rangle_a + |\gamma_{\downarrow}\rangle_a |\downarrow\rangle_a) \otimes (|\gamma_{\uparrow}\rangle_b |\uparrow\rangle_b + |\gamma_{\downarrow}\rangle_b |\downarrow\rangle_b)$$

When mode matched on the BS, coincident detection only if:

$$|\Psi^-\rangle_{\text{photons}} = |\gamma_{\uparrow}\rangle_a |\gamma_{\downarrow}\rangle_b - |\gamma_{\downarrow}\rangle_a |\gamma_{\uparrow}\rangle_b$$

Remote Ion Entanglement



$$|\Psi\rangle = (|\gamma_{\uparrow}\rangle_a |\uparrow\rangle_a + |\gamma_{\downarrow}\rangle_a |\downarrow\rangle_a) \otimes (|\gamma_{\uparrow}\rangle_b |\uparrow\rangle_b + |\gamma_{\downarrow}\rangle_b |\downarrow\rangle_b)$$

When mode matched on the BS, coincident detection only if:

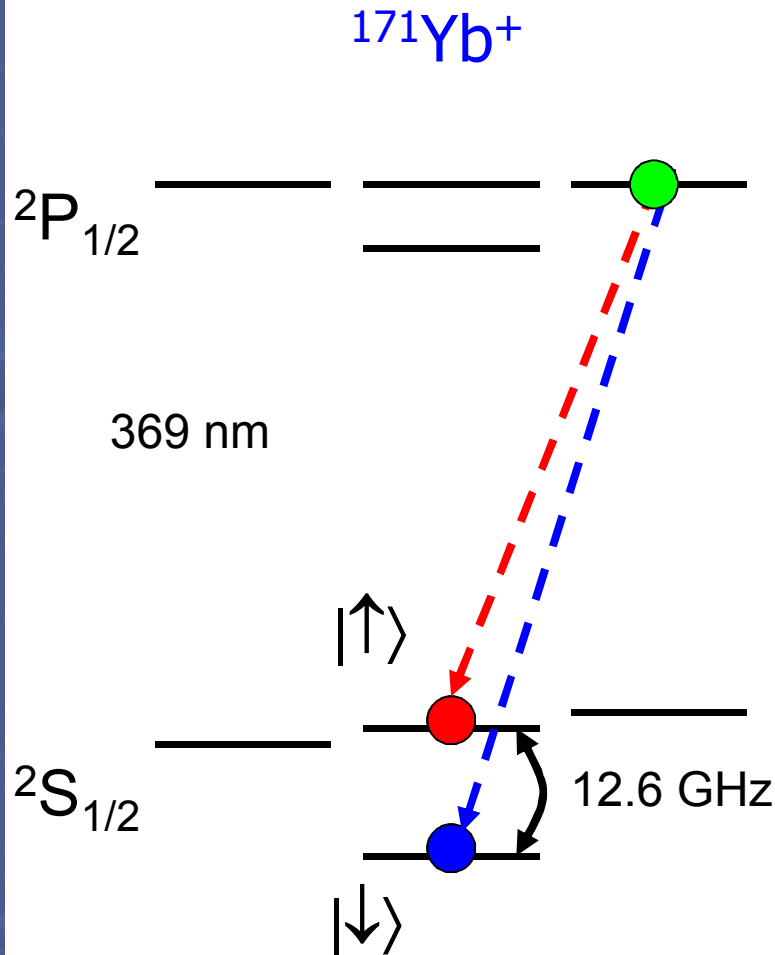
$$|\Psi^-\rangle_{\text{photons}} = |\gamma_{\uparrow}\rangle_a |\gamma_{\downarrow}\rangle_b - |\gamma_{\downarrow}\rangle_a |\gamma_{\uparrow}\rangle_b$$

This projects the ions into

$$|\Psi^-\rangle_{\text{ions}} = |\uparrow\rangle_a |\downarrow\rangle_b - |\downarrow\rangle_a |\uparrow\rangle_b$$

Coincidence “heralds” the entanglement preparation.

Remote Ion Entanglement



Ion

Hyperfine ground states

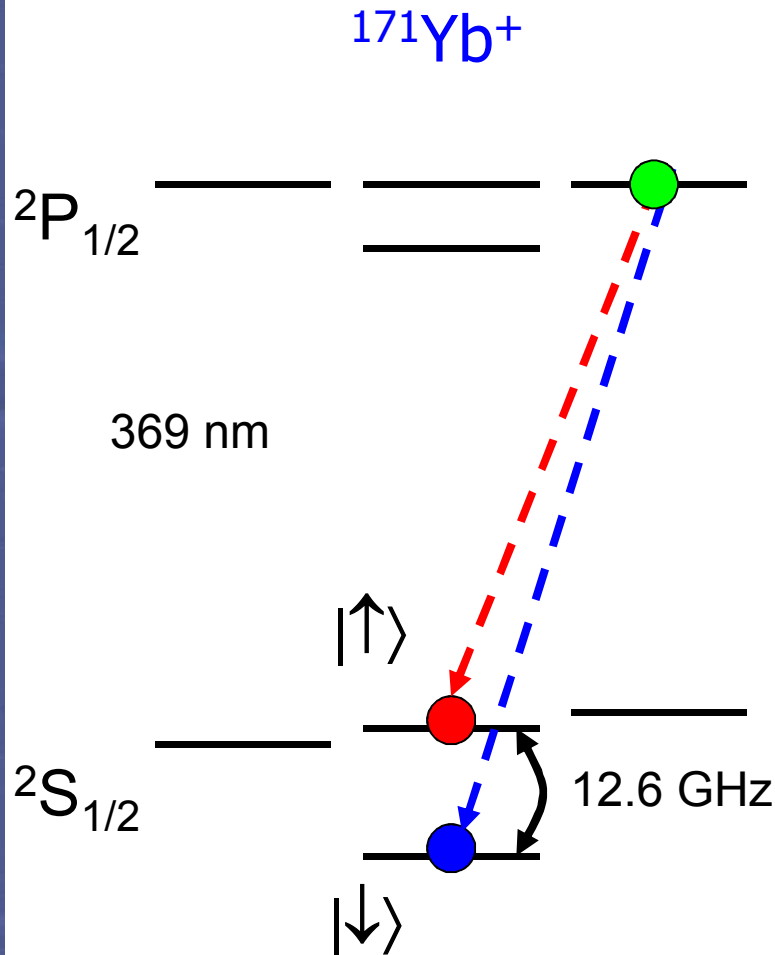
$|\uparrow\rangle$ state is $F=1, m=0$

$|\downarrow\rangle$ state is $F=0, m=0$

Photon

Two different light frequencies $|\mathbf{R}\rangle$ and $|\mathbf{B}\rangle$

Remote Ion Entanglement



Ion

Hyperfine ground states

$|\uparrow\rangle$ state is $F=1, m=0$

$|\downarrow\rangle$ state is $F=0, m=0$

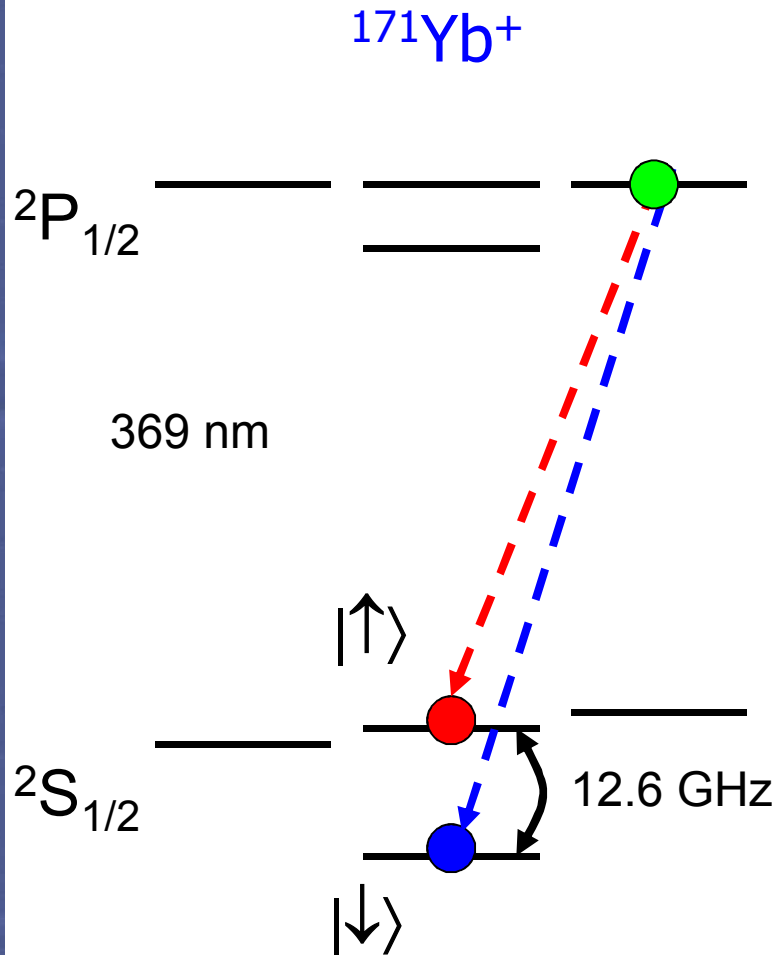
Photon

Two different light frequencies $|\mathbf{R}\rangle$ and $|\mathbf{B}\rangle$

Ion-Photon Entanglement

$$|\uparrow\rangle|\mathbf{R}\rangle - |\downarrow\rangle|\mathbf{B}\rangle$$

Remote Ion Entanglement



Ion

Hyperfine ground states

$|\uparrow\rangle$ state is $F=1, m=0$

$|\downarrow\rangle$ state is $F=0, m=0$

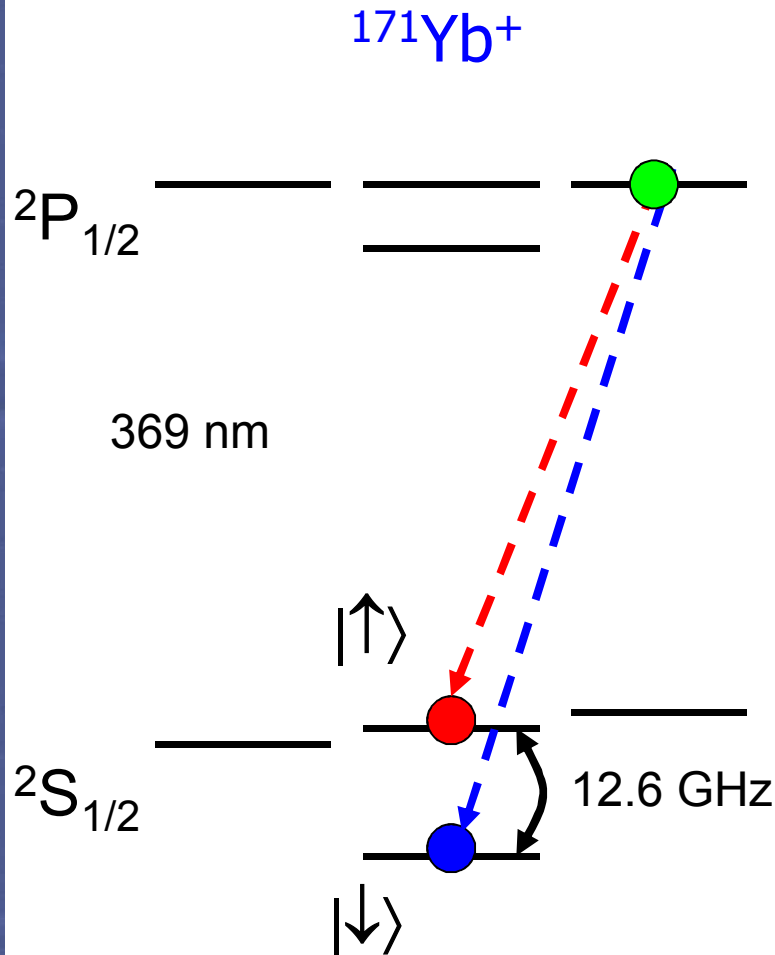
Photon

Two different light frequencies $|\mathbf{R}\rangle$ and $|\mathbf{B}\rangle$

Ion-Photon Entanglement

$$(|\uparrow\rangle|\mathbf{R}\rangle - |\downarrow\rangle|\mathbf{B}\rangle)_a \otimes (|\uparrow\rangle|\mathbf{R}\rangle - |\downarrow\rangle|\mathbf{B}\rangle)_b$$

Remote Ion Entanglement



Ion

Hyperfine ground states

$|\uparrow\rangle$ state is $F=1, m=0$

$|\downarrow\rangle$ state is $F=0, m=0$

Photon

Two different light frequencies $|\mathbf{R}\rangle$ and $|\mathbf{B}\rangle$

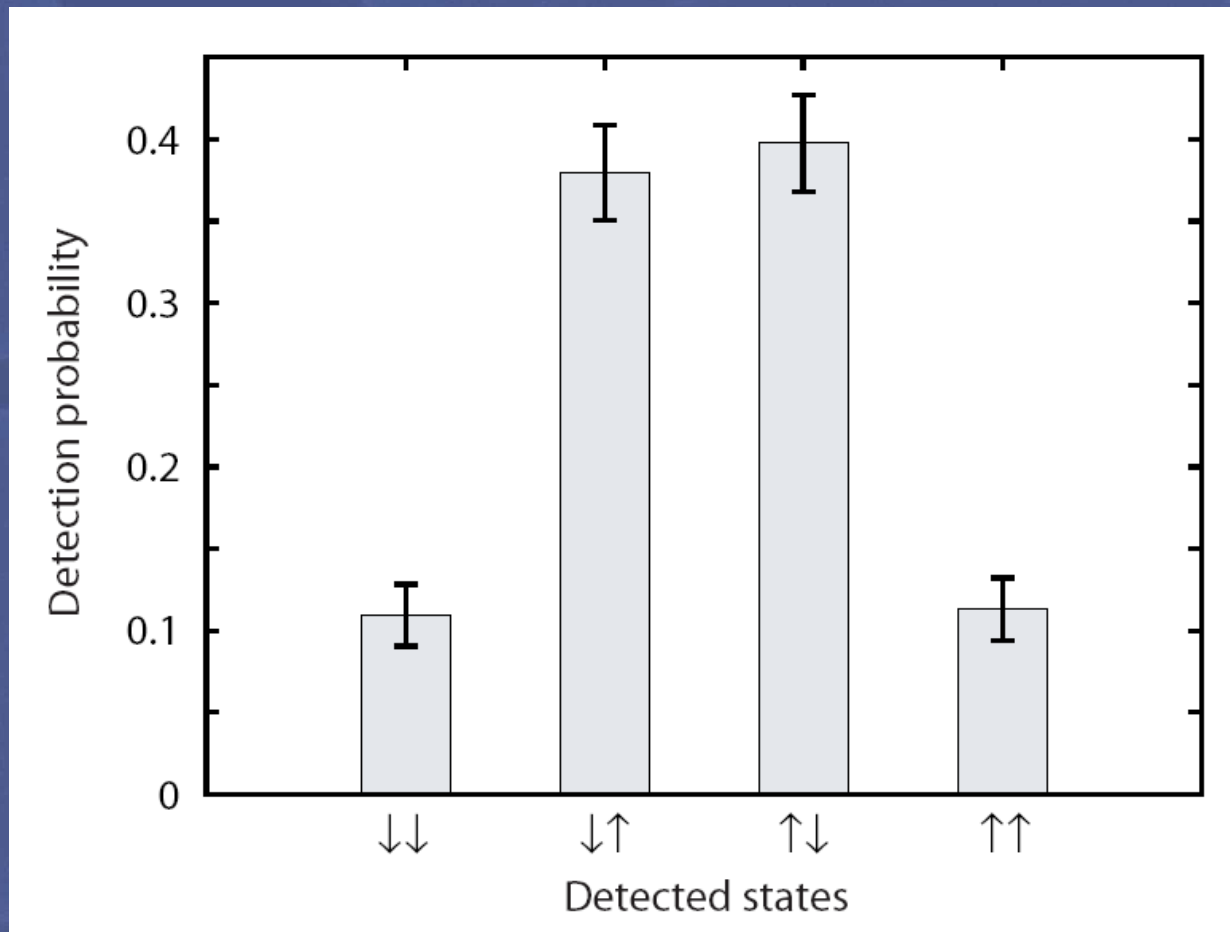
Ion-Photon Entanglement

$$(|\uparrow\rangle|\mathbf{R}\rangle - |\downarrow\rangle|\mathbf{B}\rangle)_a \otimes (|\uparrow\rangle|\mathbf{R}\rangle - |\downarrow\rangle|\mathbf{B}\rangle)_b$$

Coincidence projects ions onto:

$$|\Psi^-\rangle_{\text{ions}} = |\uparrow\rangle_a |\downarrow\rangle_b - |\downarrow\rangle_a |\uparrow\rangle_b$$

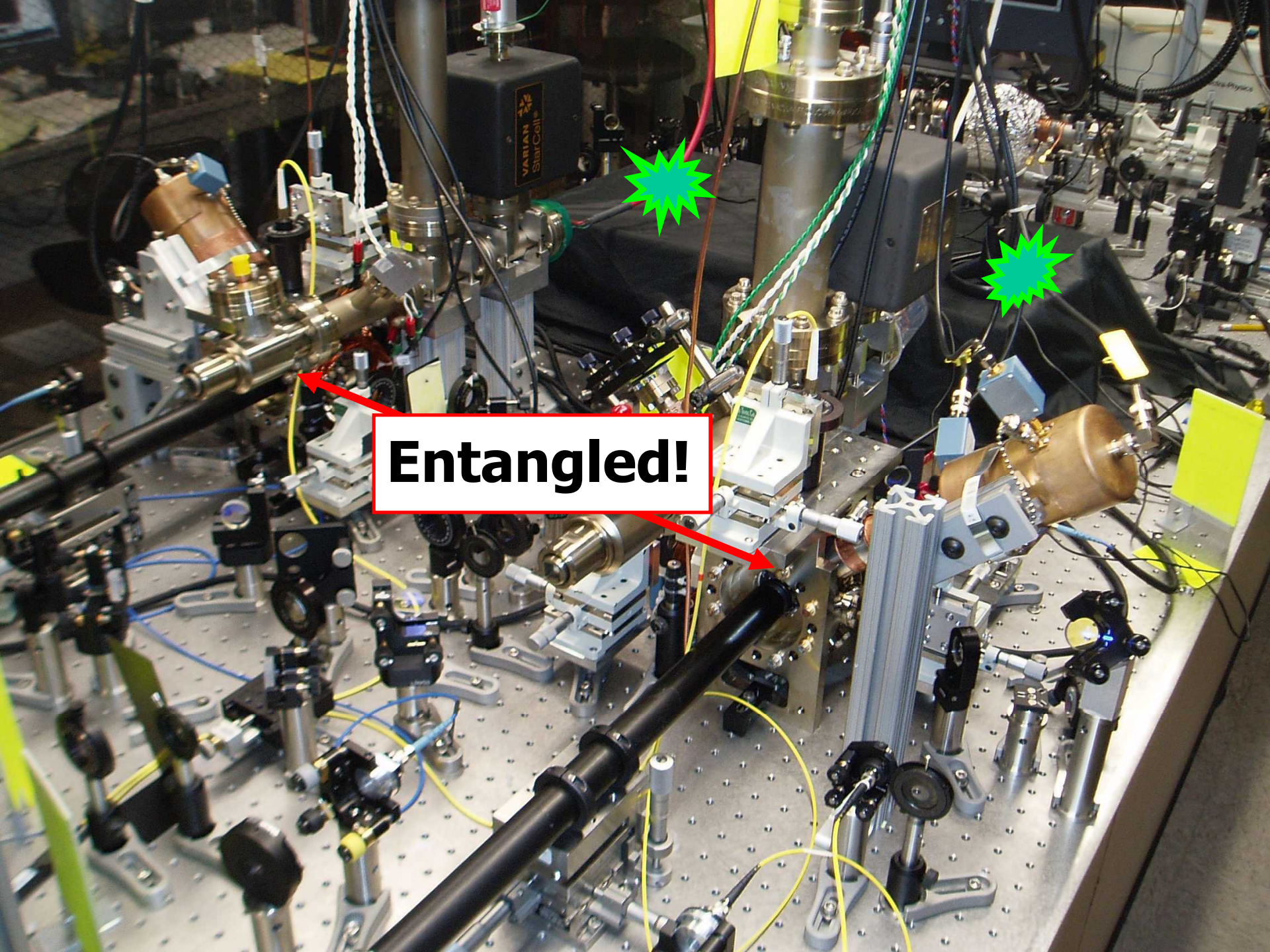
Qubit state measurements



Expected ion state is:

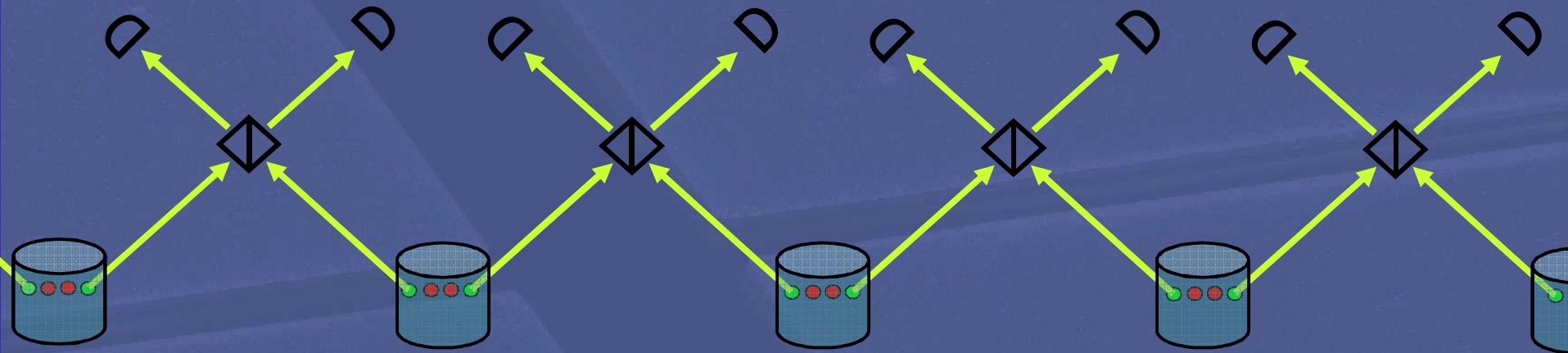
$$|\Psi^-\rangle_{\text{ions}} = |\uparrow\rangle_a |\downarrow\rangle_b - |\downarrow\rangle_a |\uparrow\rangle_b$$

Success probability per trial $P = \frac{1}{4}[\frac{1}{2}\eta\zeta T\beta P_{\text{exc}}(\Delta\Omega/4\pi)] = 3 \times 10^{-9}$



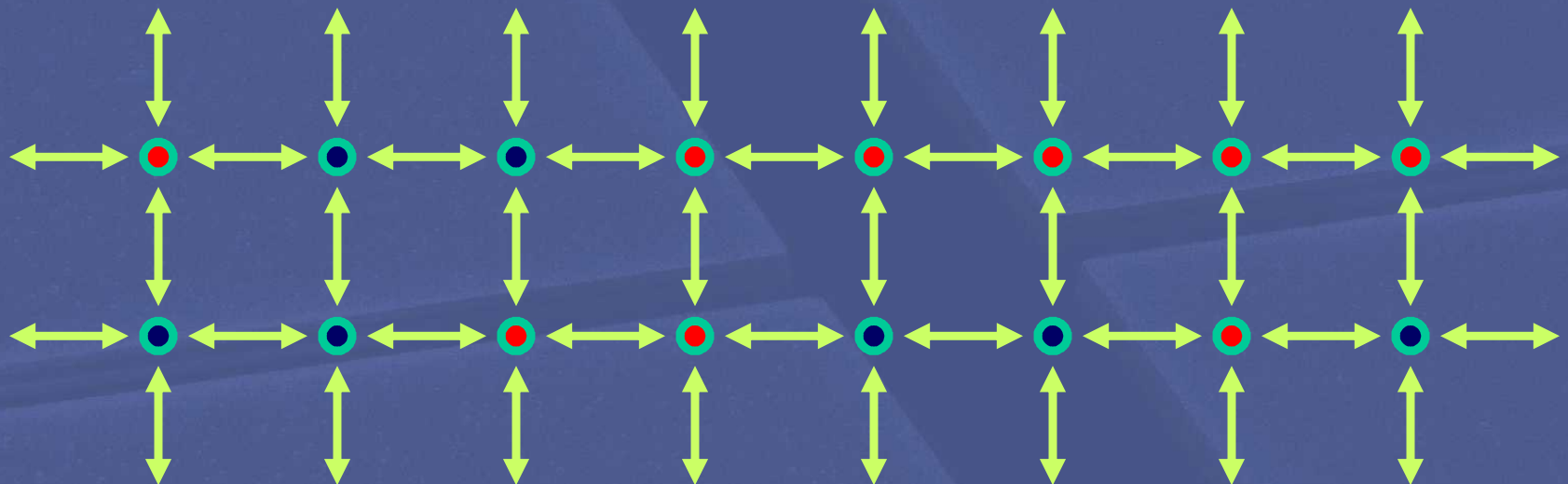
Entangled!

Scalable even though probabilistic



Quantum Repeater Network

Duan et. al., *Quan. Inf. Comp.* 4, 165 (2004)

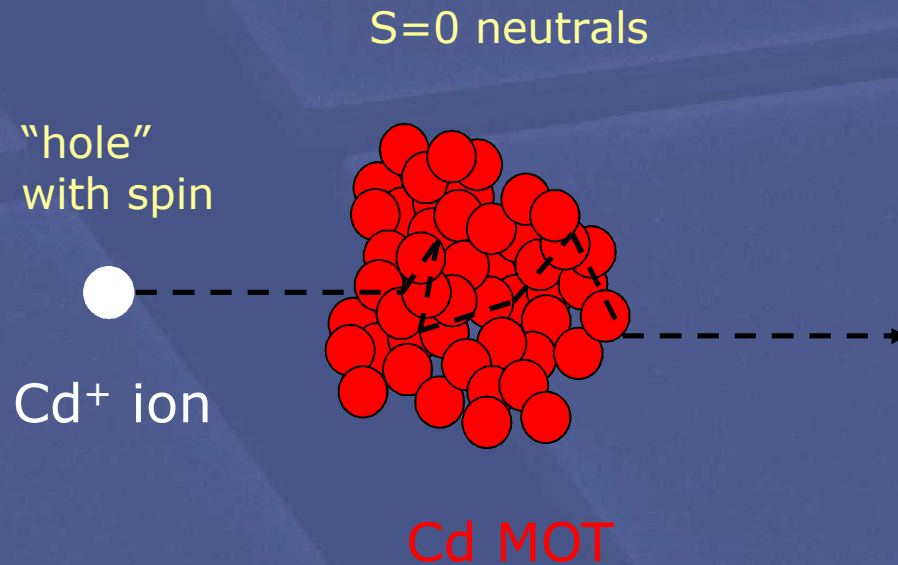


Cluster State Quantum Computing

Raussendorf and Briegel, *PRL* 86, 910 (2001)
Duan and Raussendorf, *PRL* 95, 080503 (2005)

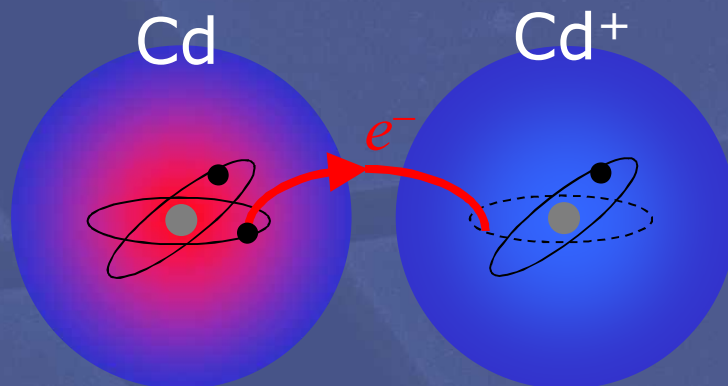
Combining ions and neutrals

Single ion and a magneto-optical trap



Combining ions and neutrals

Single ion and a single neutral atom



(i) ions entangled

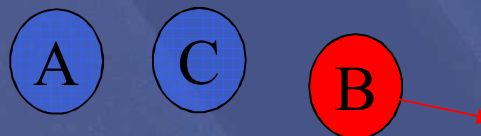


(ii) add e^- to ion B



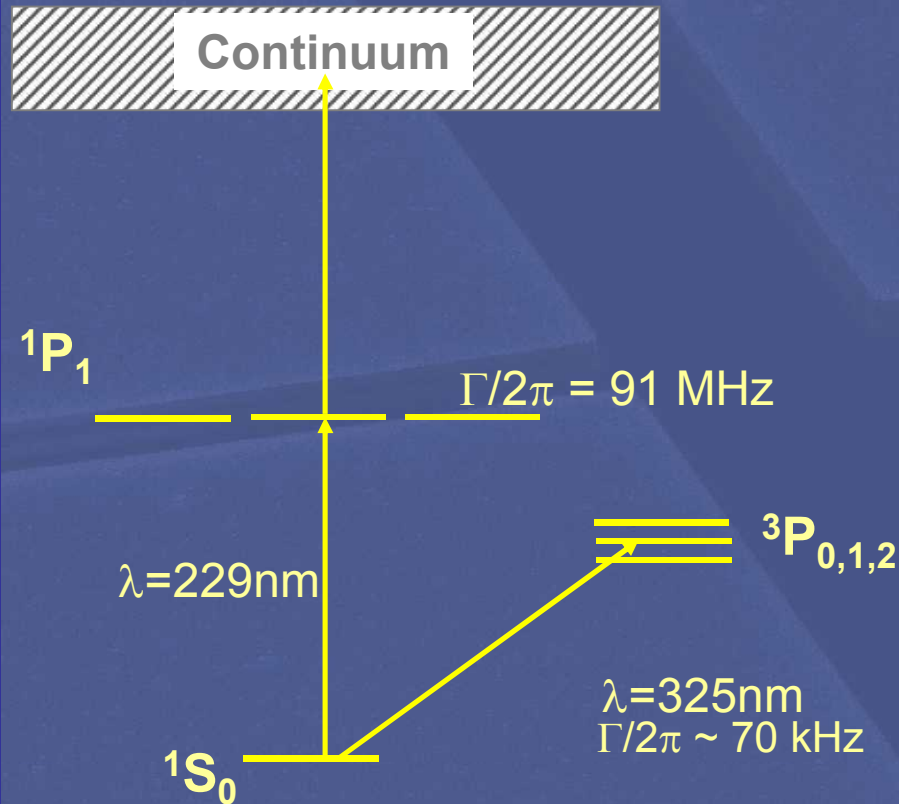
$S=0$

(iii) move B with protected qubit in nucleus



Cadmium Energy Level Diagram

Even Isotopes; $I=0$

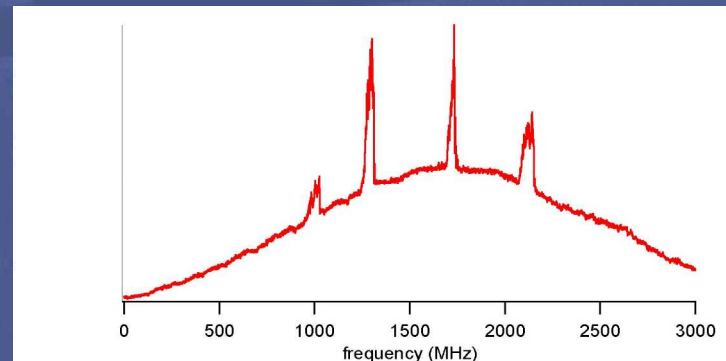
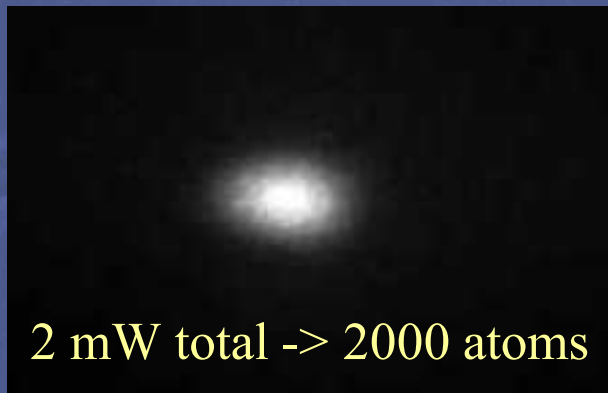


Pros:

- simple structure
- good vapor pressure at room temperature
- triplet manifold useful for optical clock studies

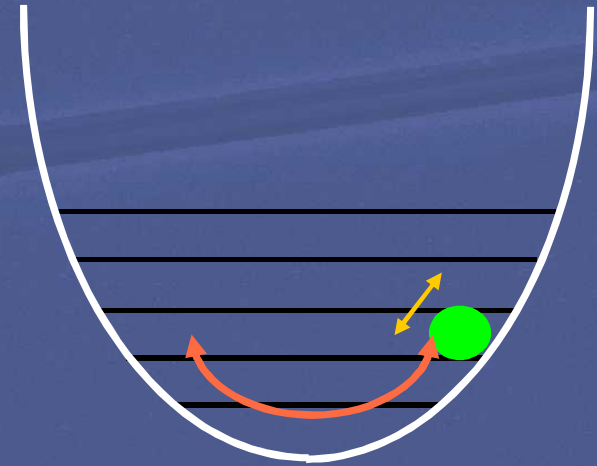
Cons:

- Low power! (few mW) ($I_{\text{sat}} = 1\text{W/cm}^2$)
- Small beams (few mm)
- Large excited state linewidth requires large B-field gradient (500G/cm)



2a. Microfabricated traps

$$\Psi_{RF} \propto |\nabla V(x, y, z)|^2$$



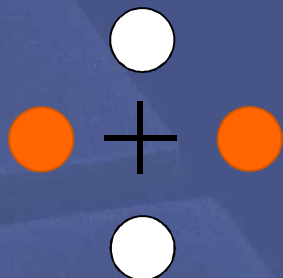
Equation of motion:
$$z(t) = \left[1 + \frac{\sqrt{2}\omega}{\Omega} \cos(\Omega t) \right] z_0 \cos(\omega t)$$

Micromotion **Secular motion**

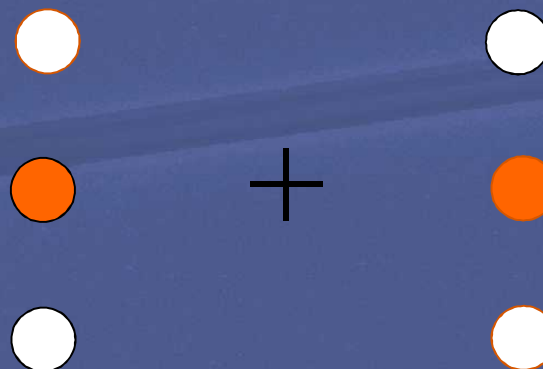
Ω = RF drive frequency
 ω = secular frequency

RF DC

Trap geometries



$\omega = 1$
depth = 1



$\omega = .52$
depth = .078

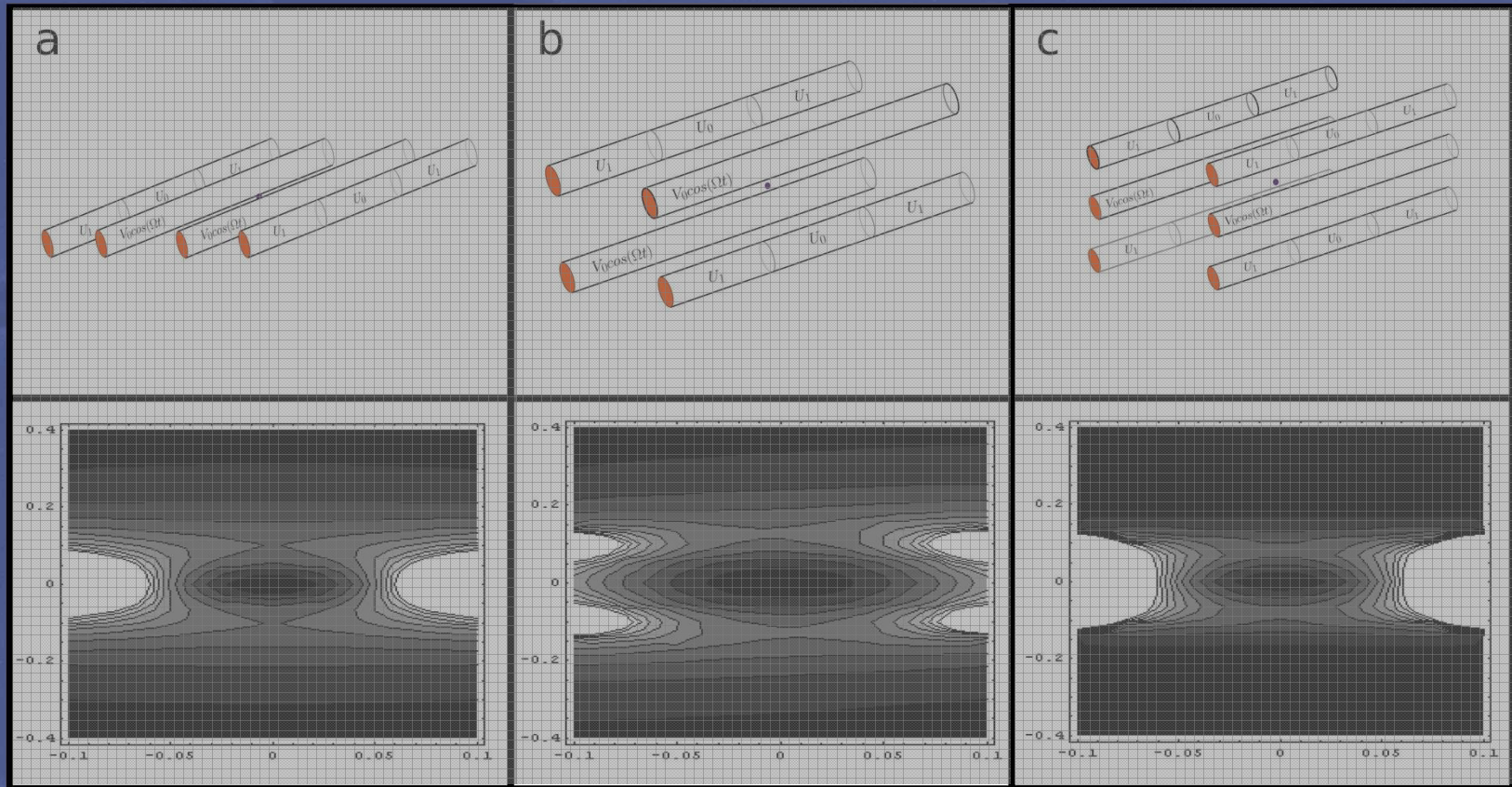


$\omega = .32$
depth = .051

×



Comparative geometries

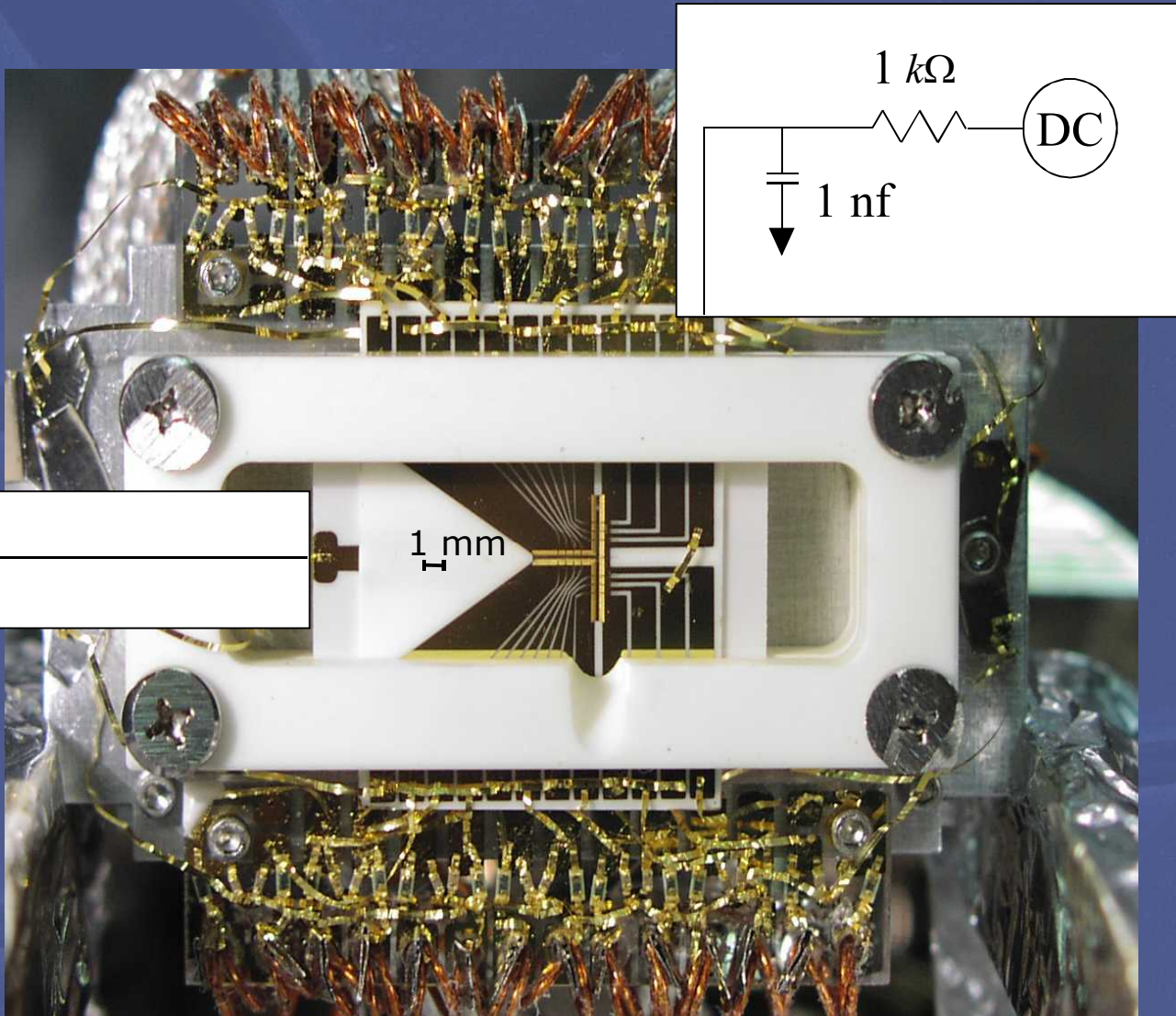


$\omega = .32$
depth = .051

$\omega = 1$
depth = 1

$\omega = .52$
depth = .078

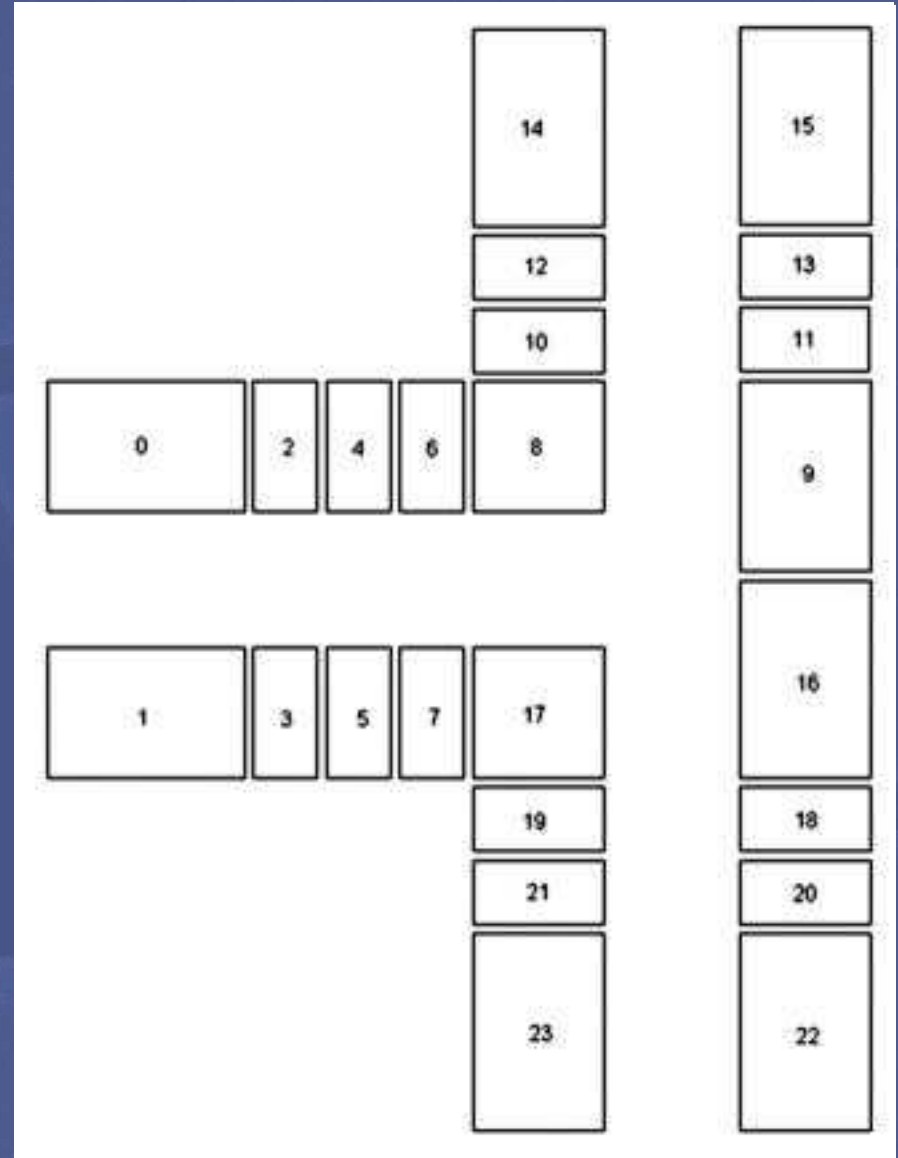
T junction trap



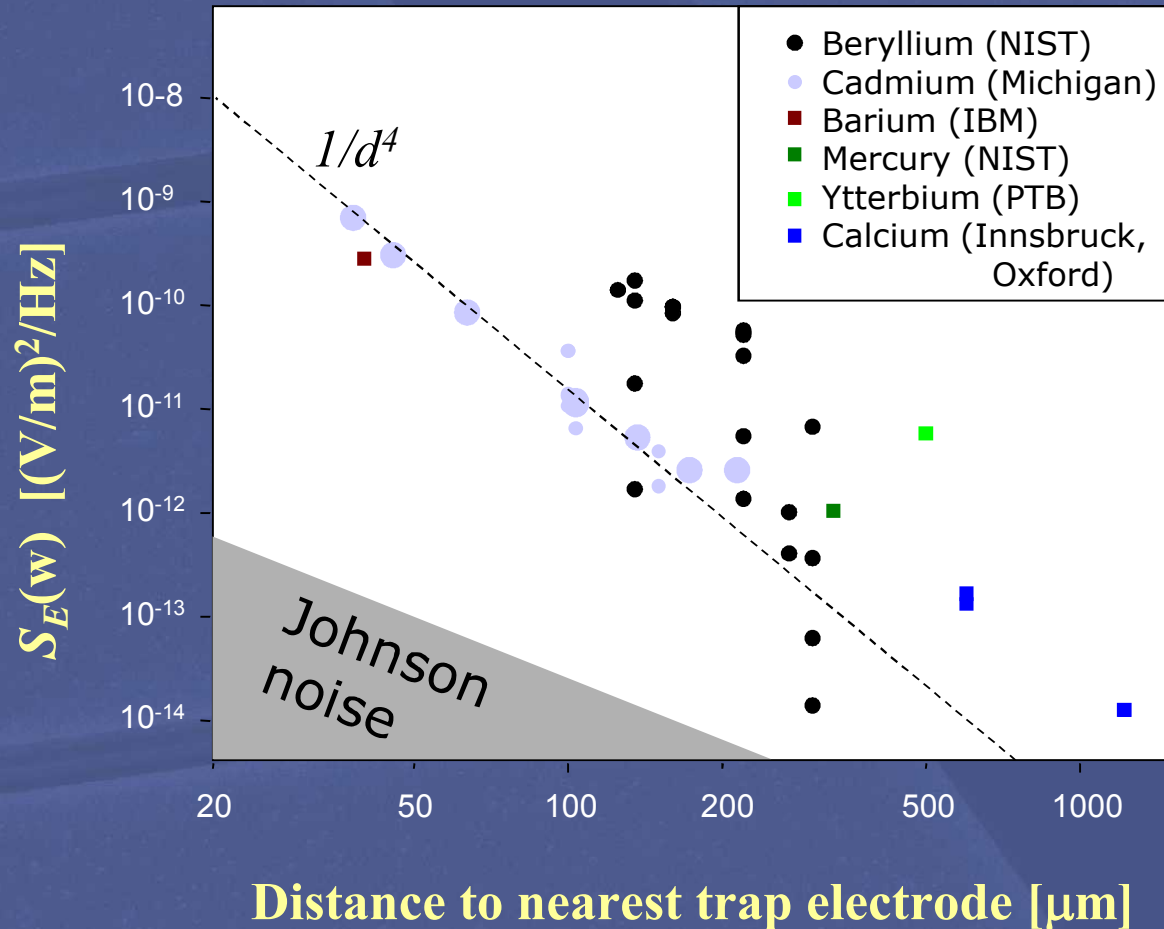
Results: Shuttling

Probability of successfully:

1. Turning the corner, from electrode 8 to 10:
 - 881/882 ~ 100%
2. Returning, from electrode 10 to 8:
 - 116/118 ~ 98%
3. Separation
 - 37/64 ~ 58%
4. Total success rate:
 - 12/51 ~ 24%

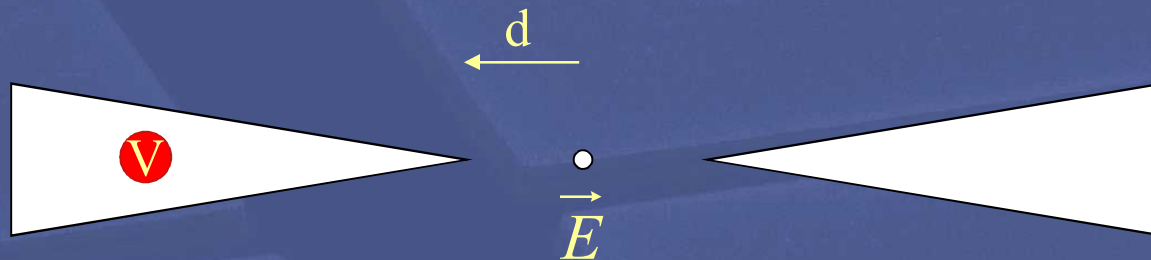


2b. Motional heating vs. ion-electrode distance



$$\dot{\bar{n}} = \frac{e^2}{4m\hbar\omega} S_E(\omega)$$

Characterizing anomalous 'patch potential' heating



Find ground state heating rate given spectral density of electric field noise.

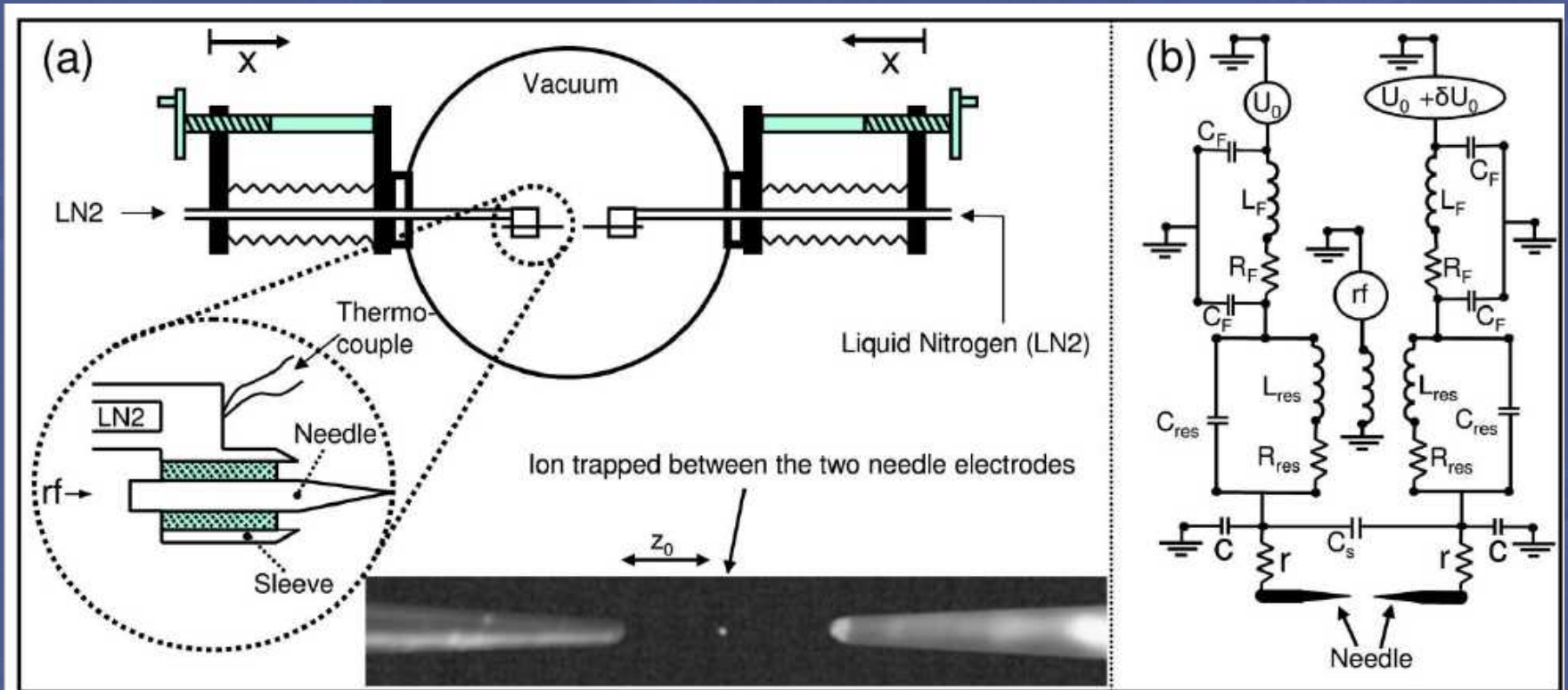
$$\begin{aligned}\Gamma_{0 \rightarrow 1} &= \frac{1}{\hbar^2} \int_{-\infty}^{\infty} d\tau \cdot e^{i\omega_z \tau} \langle E(t)E(t+\tau) \rangle \left| \langle 0 | qz | 1 \rangle \right|^2 \\ &= \frac{e^2}{4m\hbar\omega_z} S_E(\omega_z)\end{aligned}$$

Find the electric field noise given the ion-electrode distance d , patch size s , and summed over n patches.

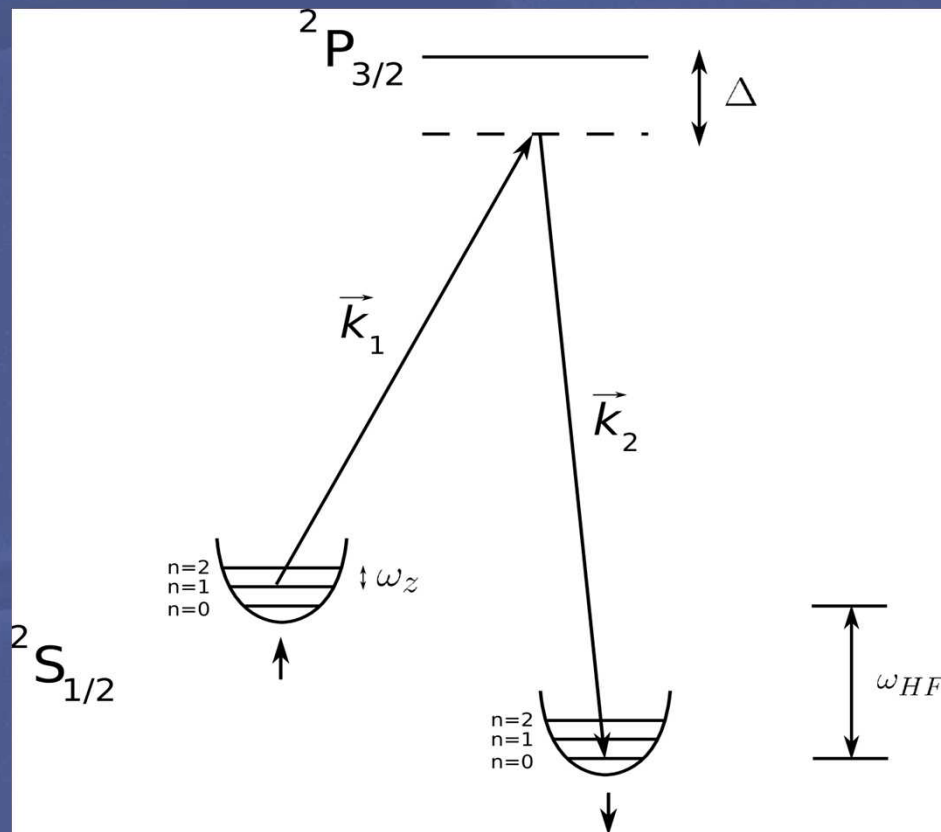
$$E_z = V_n \xi_{n,s,d}$$

$$S_E(\omega_z) = 2 \left(\sum_n \xi_{n,s,d}^2 \right) S_V(\omega_z)$$

Needle trap



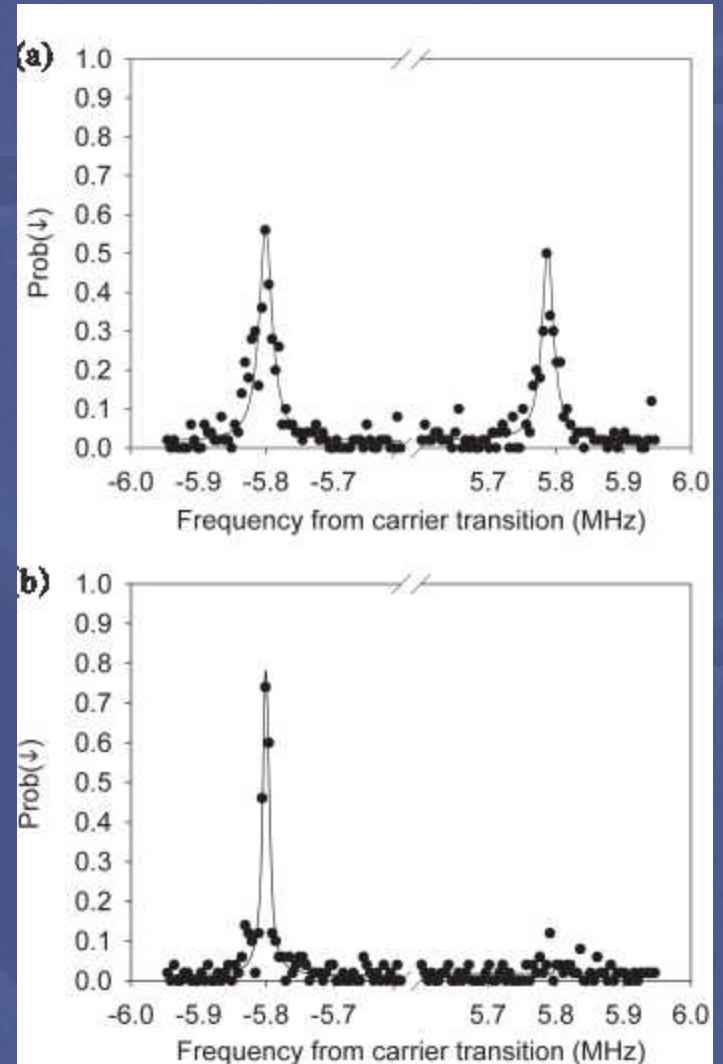
Sideband thermometry



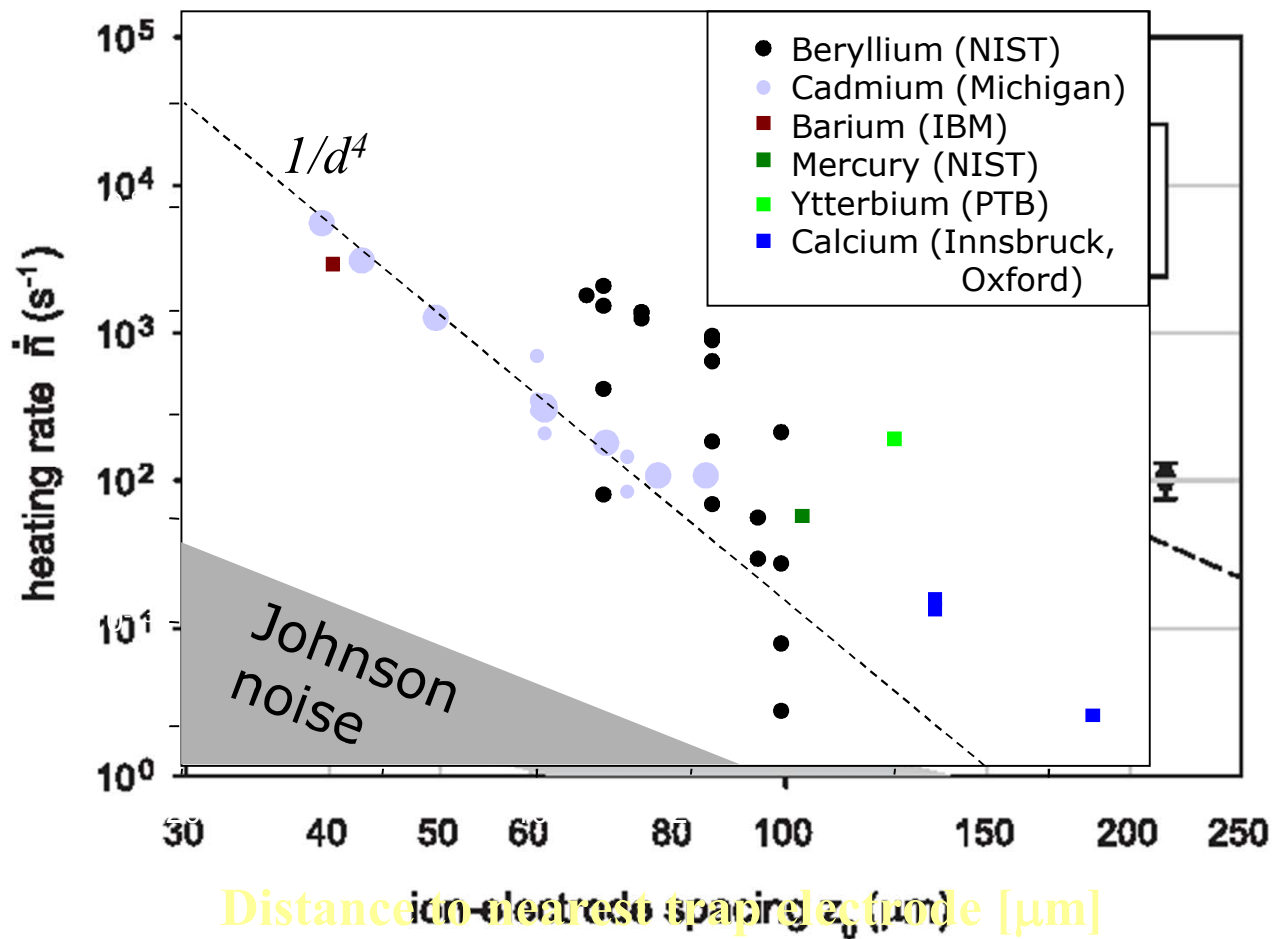
$$\Omega_{n,n} = \Omega_0$$

$$\Omega_{n,n-1} = \Omega_0 \eta \sqrt{n}$$

$$\Omega_{n,n+1} = \Omega_0 \eta \sqrt{n+1}$$

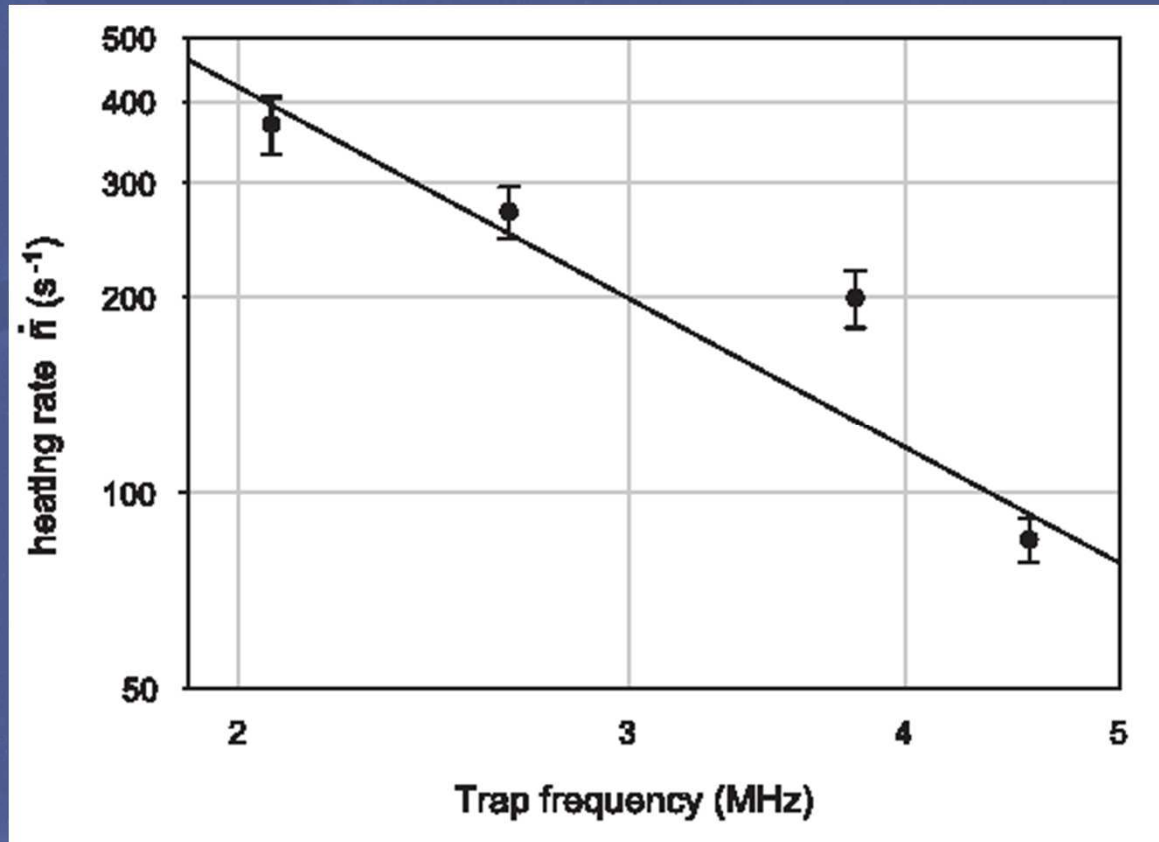


Results: Heating vs. distance



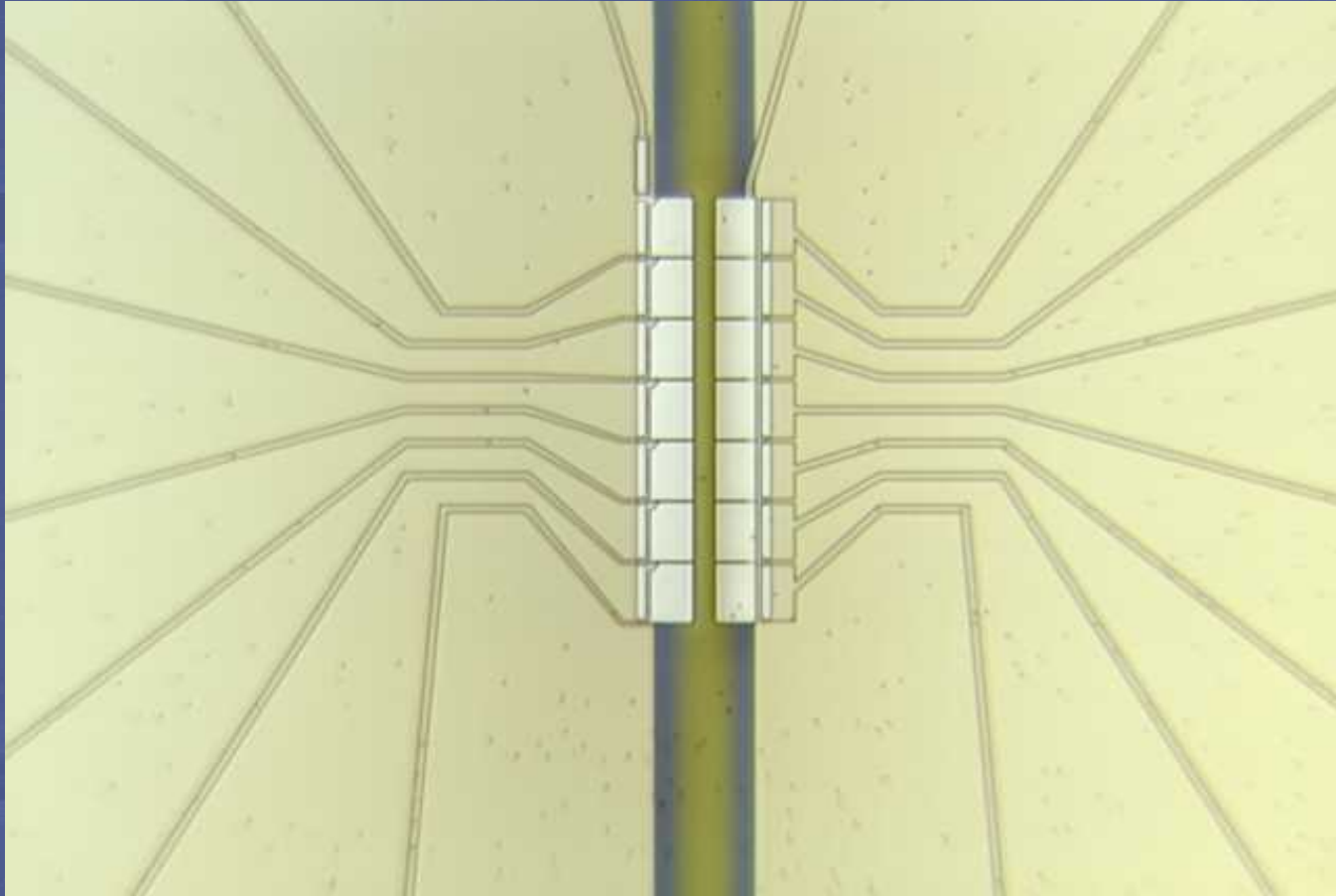
$$S_E(\omega) \propto d^{-3.5 \pm 1.1}$$

Results: Heating vs Frequency



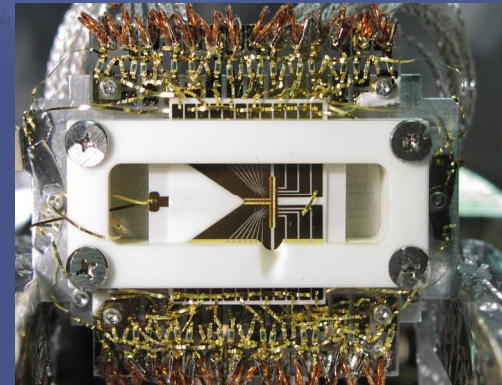
$$S_E(\omega) \propto \omega^{-.8 \pm .2}$$

2c. Examples of microfabricated traps



Advantages of microfabricated traps

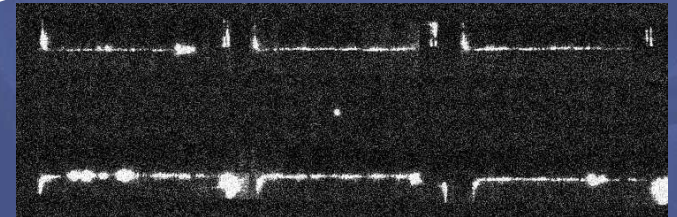
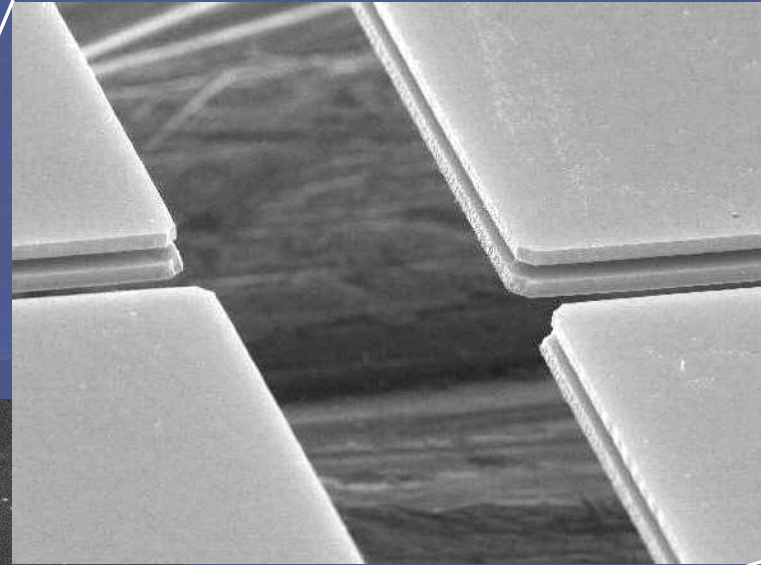
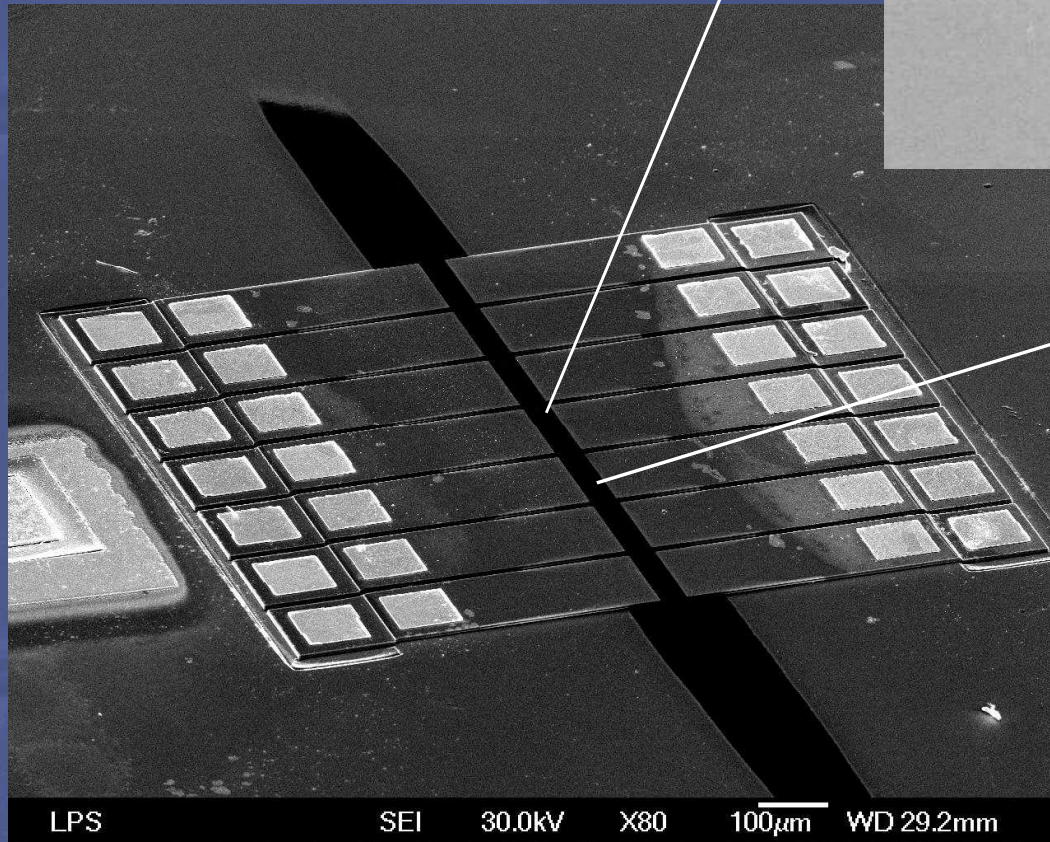
- No assembly (except wire bonding)
 - No alignment
- Small electrodes
- Scalable – change photolithographic mask
 - Easy to change design
- On board filters for DC electrodes, control electronics integration



Disadvantages of microfabricated traps

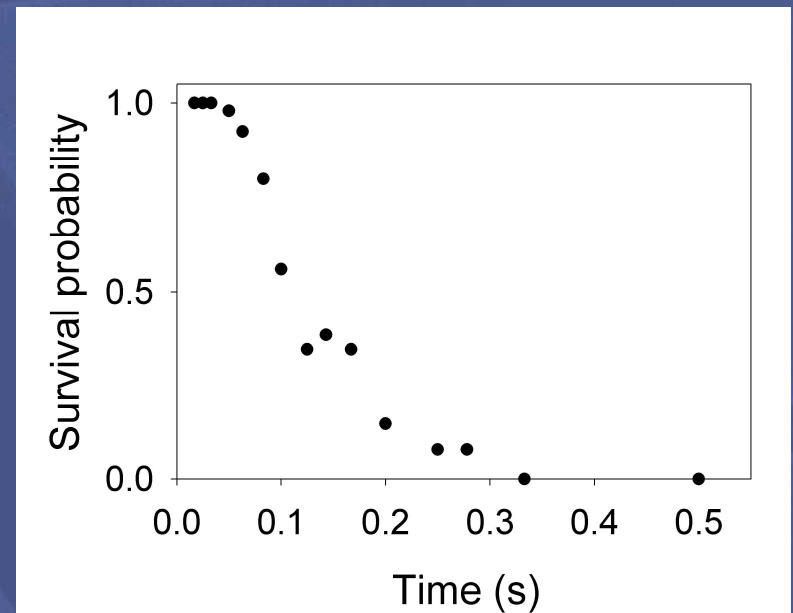
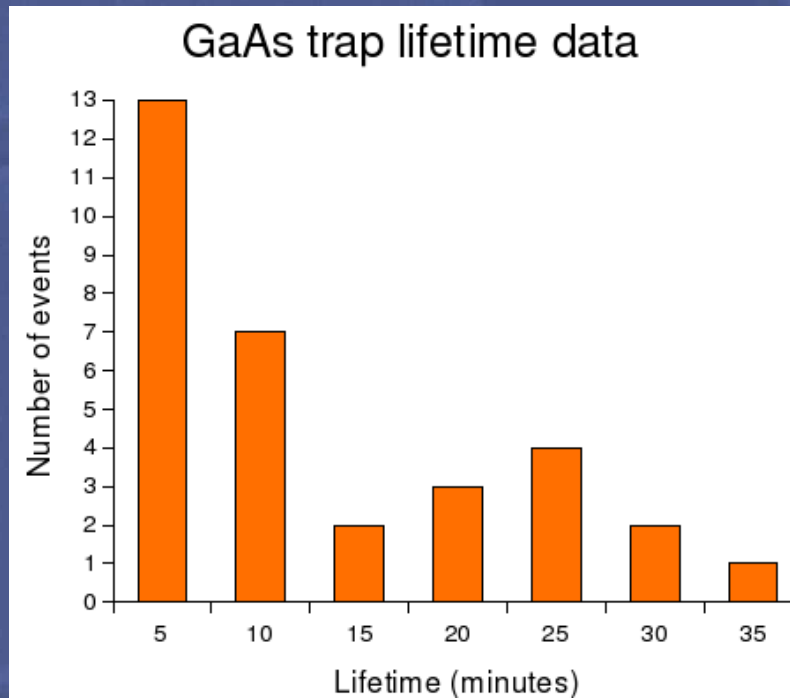
- Material properties
 - Lossy conductors, high parasitic capacitance, low breakdown insulators
 - Power dissipation: $V^2 \Omega C (R C \Omega + \tan \delta)$
- Restricted physical dimensions
 - Limited vertical thicknesses
- Small size drastically increases heating

Trapping Parameters



Depth = 3 x room temperature
 $\omega/2\pi = 1$ MHz

Results: lifetime with and without cooling

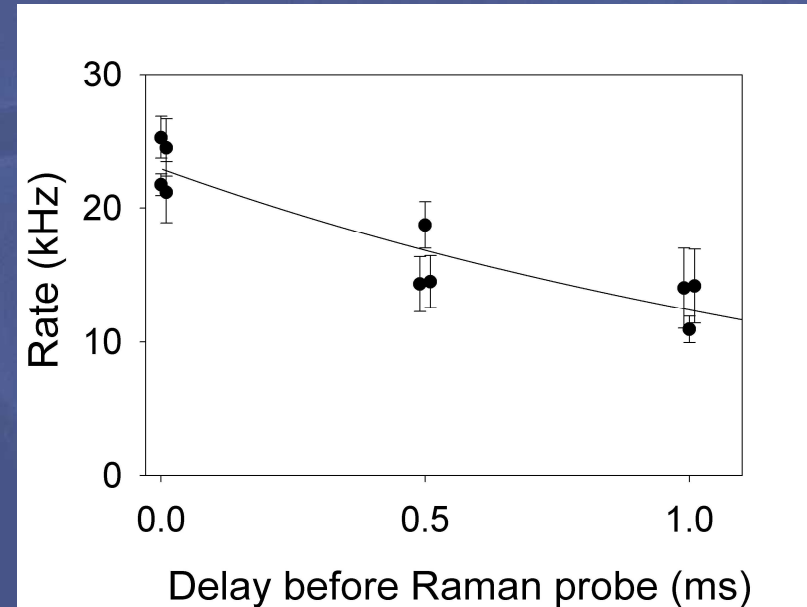
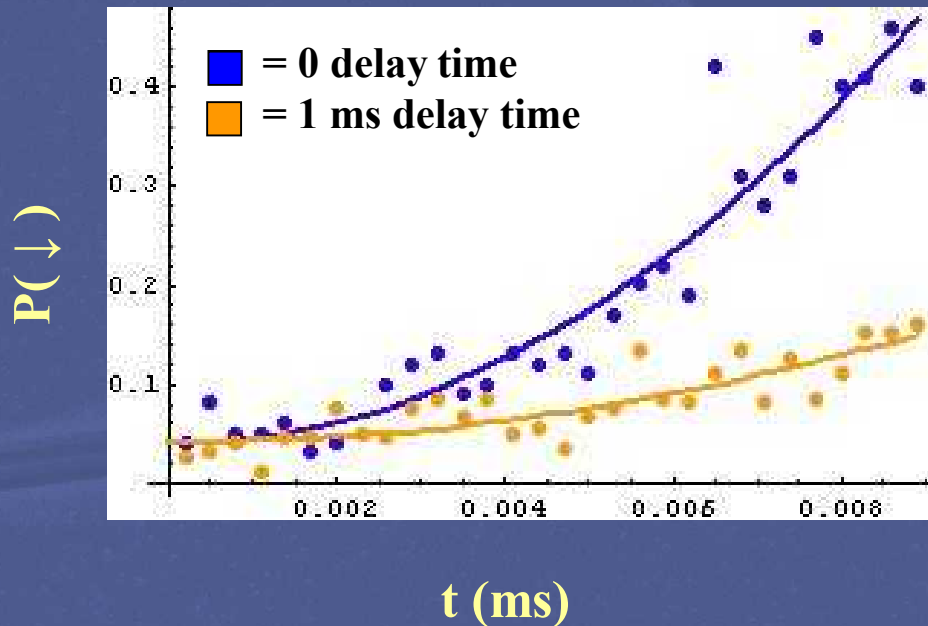


Results: heating rate

$$\Omega_{n,n} = \Omega_0 e^{-\eta^2/2} L_n^2(\eta^2)$$

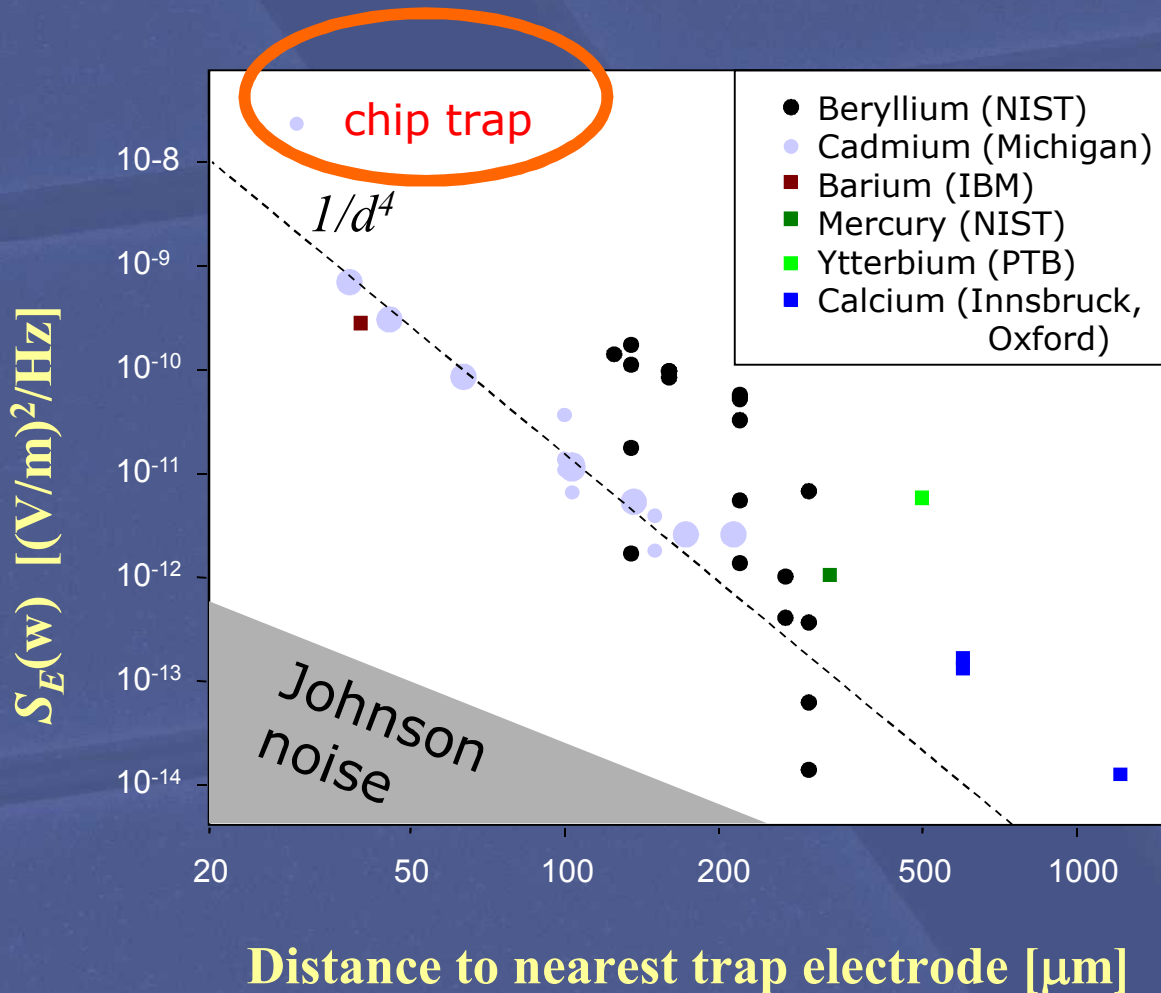
$$S(t) = \sin^2(\Omega_{n,n} t / 2)$$

$$= \frac{\Omega_0 t^2}{4} (1 - 2\eta^2 \Gamma T)$$

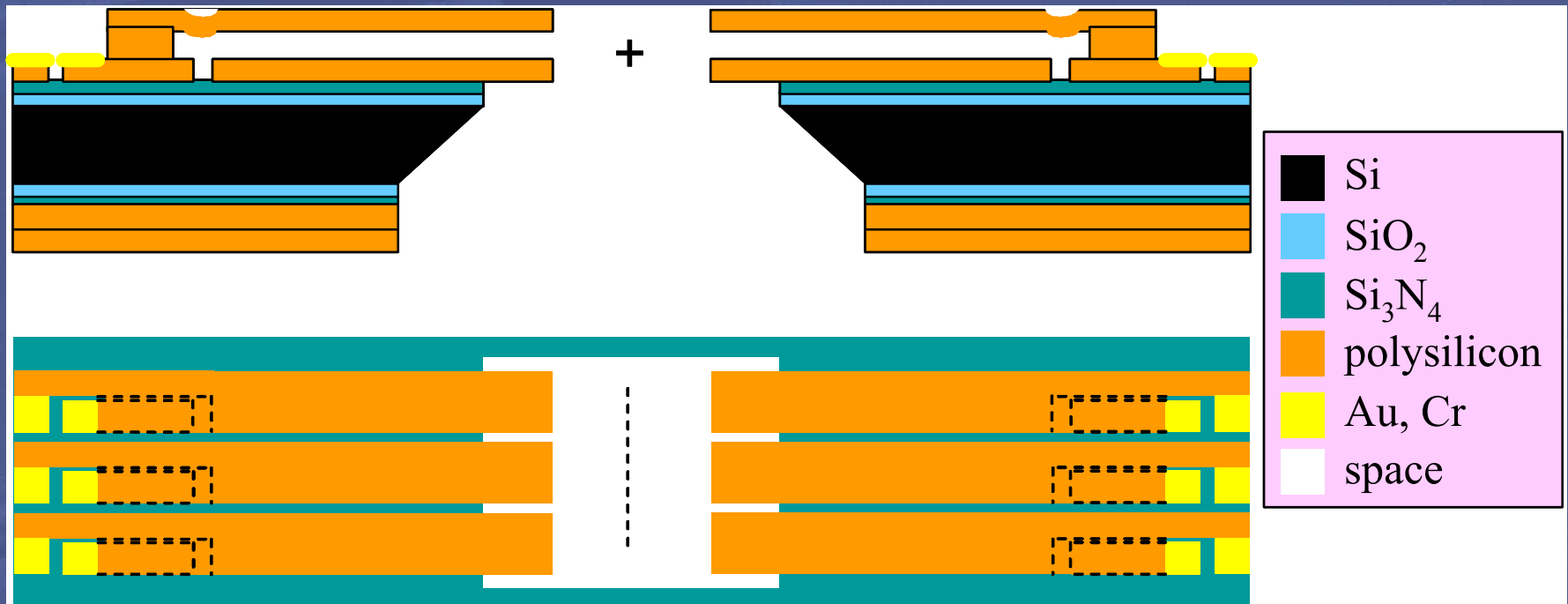


Heating rate:
 1 ± 0.5 quanta/microsecond

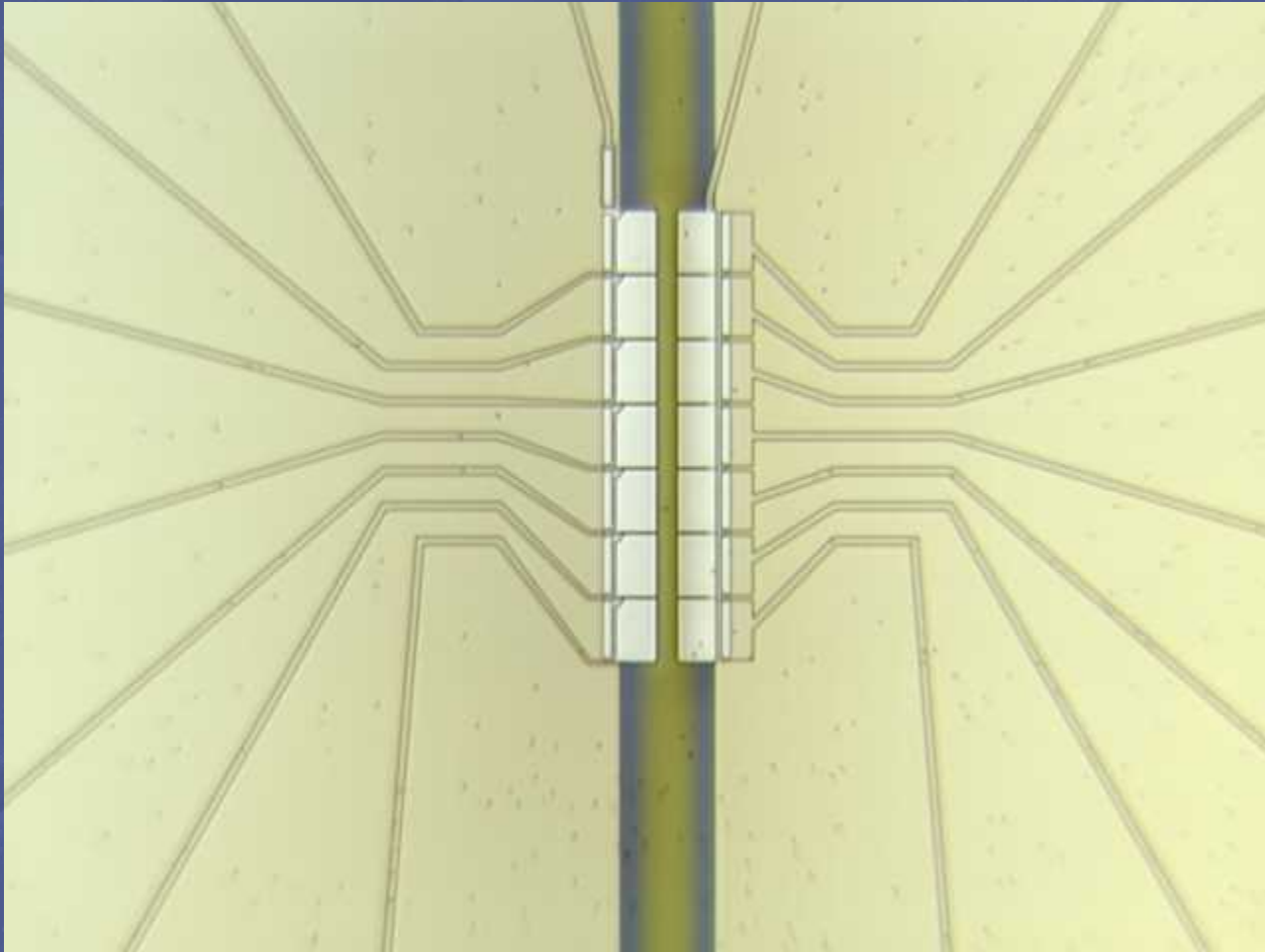
Heating rate relative to other traps



Polysilicon MEMS trap



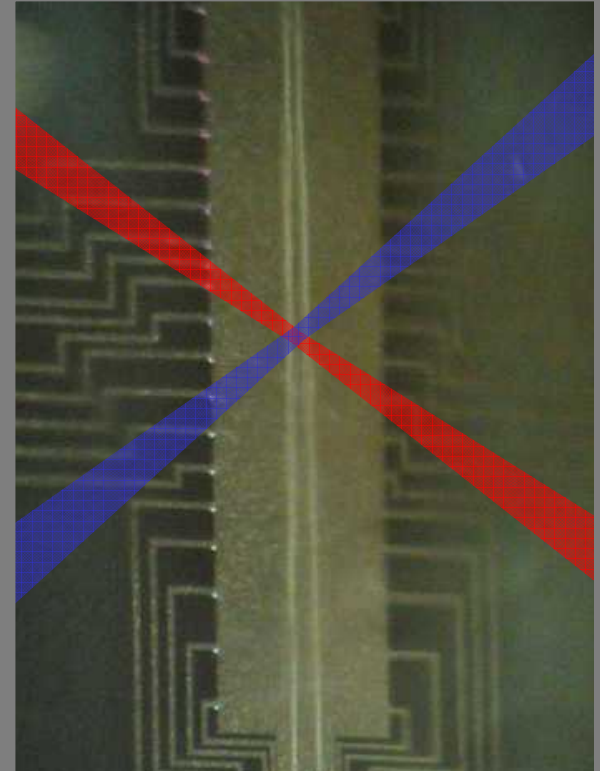
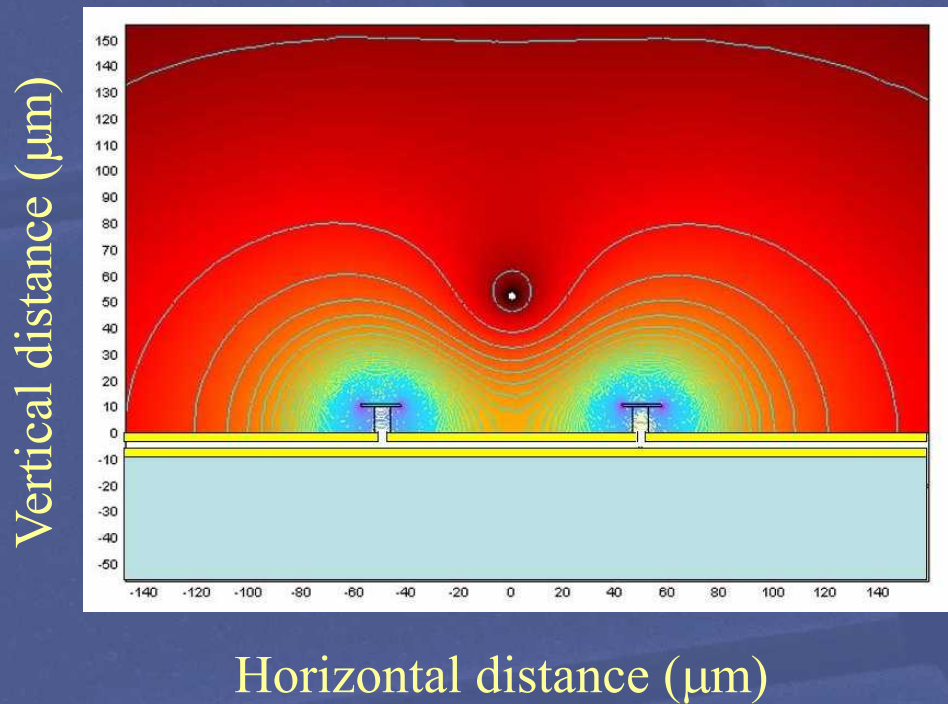
Polysilicon MEMS trap



Si/SiO₂ “surface” trap

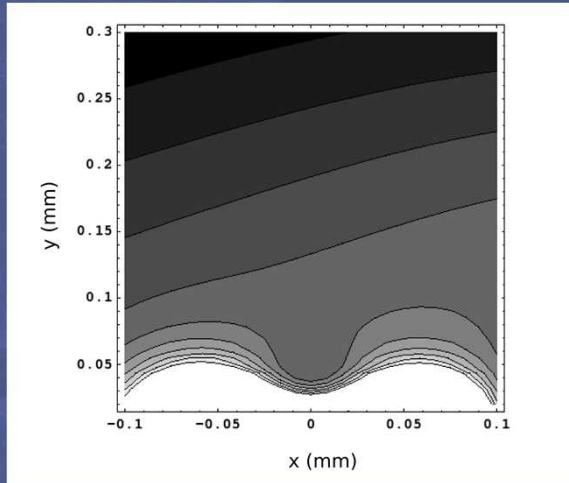
R. Slusher, Lucent

Ponderomotive potential

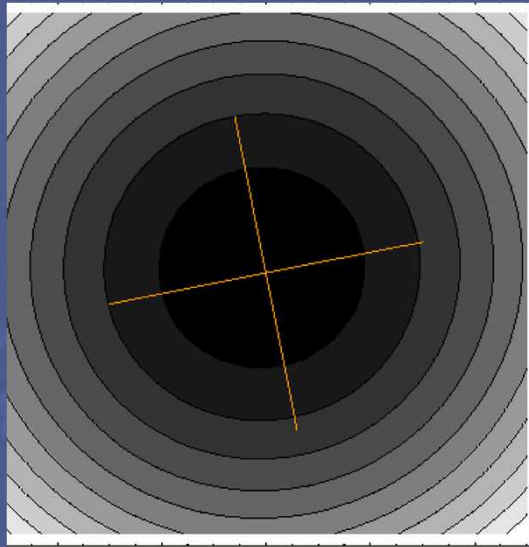


S. Seidelin, et al. Phys. Rev. Lett. **96**, 253003 (2006)

Results: Tilting the principal axes



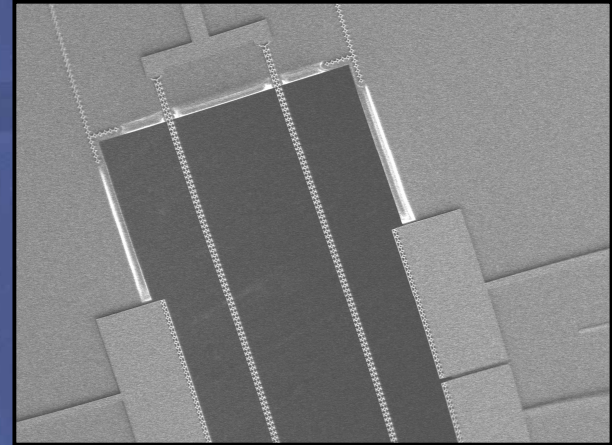
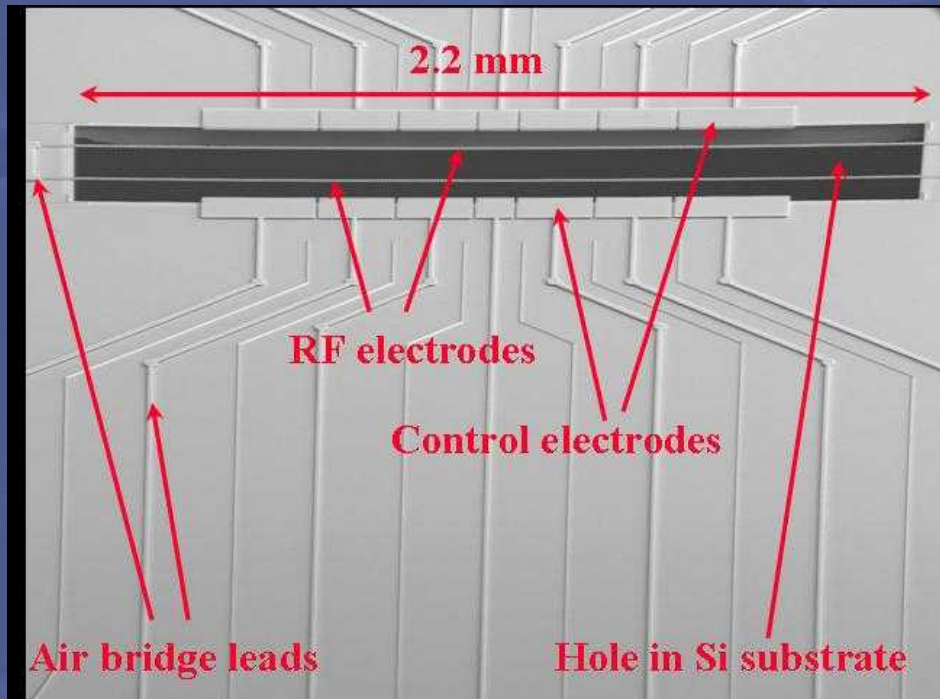
The principal axes are the directions in which the ion's motion is uncoupled from the other directions. The laser cannot cool the ion's motion if it is perpendicular to one of the principal axes.



3.12 V	370 V@32 MHz + 2.34 VDC	2.34 V	370 V@32 MHz + 2.34 VDC	6.12 V
1.90 V				1.22 V
3.12 V				6.12 V

Tungsten traps

M. Blain, C. Tigges, J. Hudgens, Sandia



Summary

Grad Students

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to Stanford

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to NIST-G'burg

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Trapped Ion Quantum Computing

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Foundation



US Defense
Advanced Research
Projects Agency



Disruptive Technology Office



Michigan
FOCUS Center



US Army
Research Office